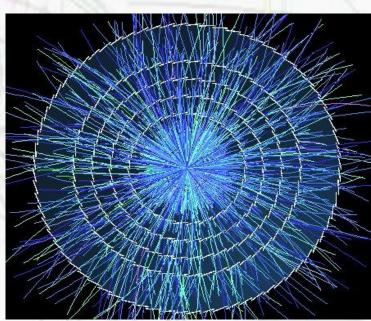
Semiconductor Tracking and Vertex Detectors at Future High Energy Physics Experiments

Phil Allport The University of Liverpool 28/09/10 3<sup>rd</sup> Marie Curie Particle Detectors (MC-PAD) Network Training Event

- Brief Overview of the Large Hadron Collider
- Detectors and Technologies
- Recent Performance
- LHCb and ALICE Upgrade Plans
- ATLAS and CMS at the super-LHC
- Conclusions



# **The Large Hadron Collider Accelerator**

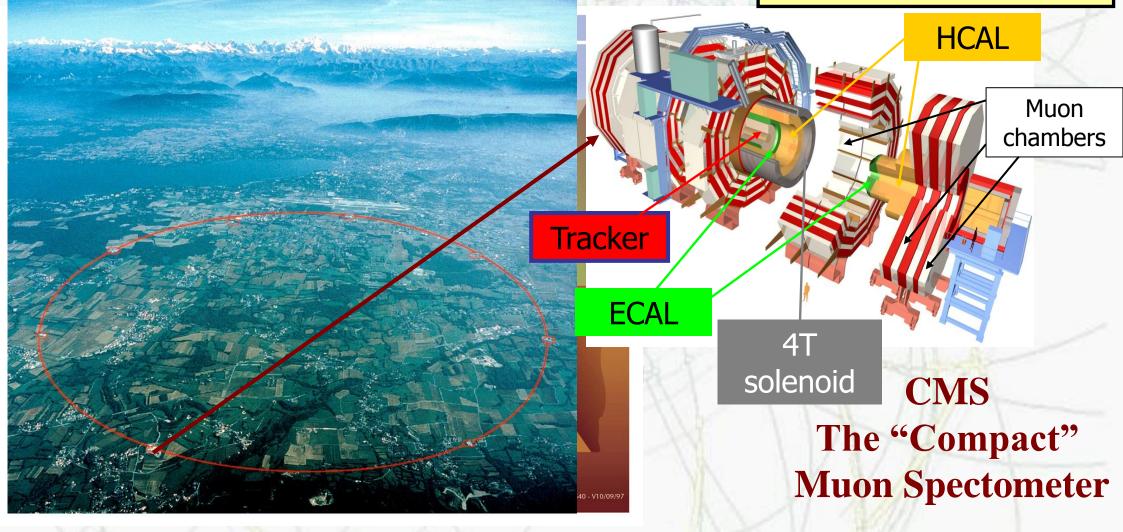


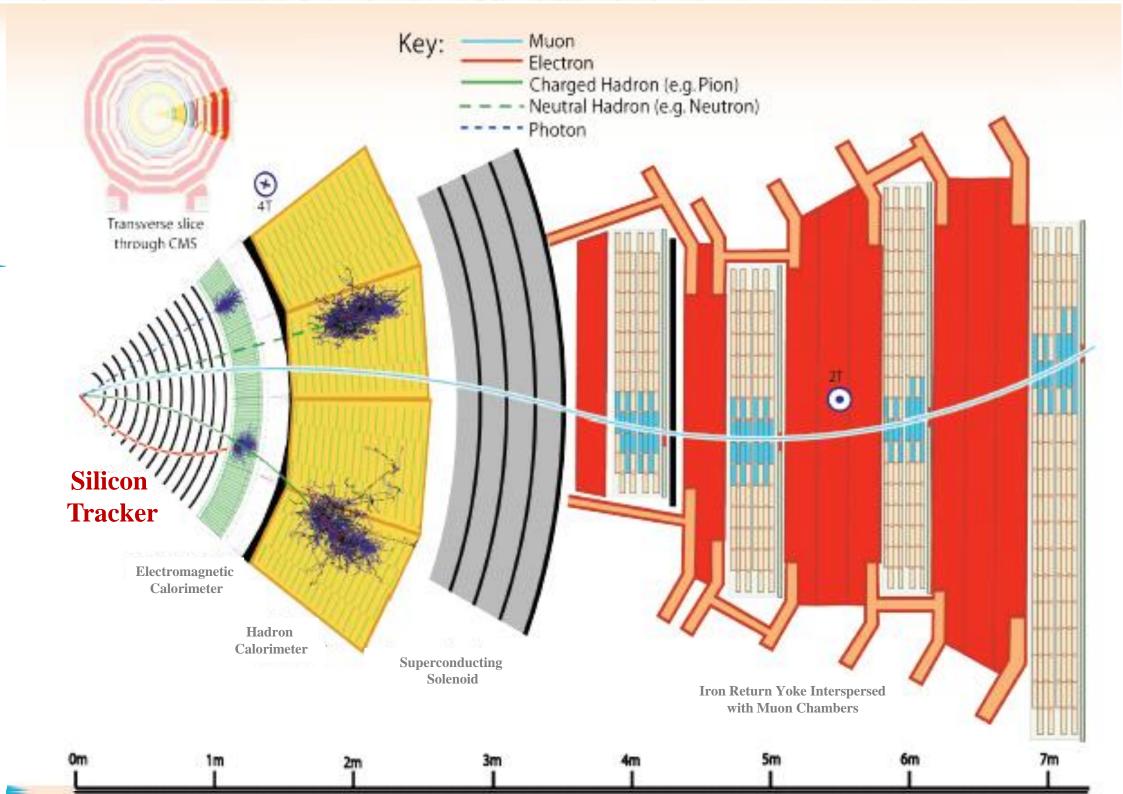
## **Experiments at the LHC**

### **Collider Experiments**

CERN Geneva2 Giant General Purpose Detectors at the LHCThe Large Hadron Collider 14 TeV: Proton on Proton

Total weight: 12,500 t Overall diameter: 15 m Overall length 21.6 m Magnetic field 4 T





## **Physics of Micro-strip Silicon Detectors**

- Highly segmented silicon detectors have been used in Particle Physics experiments for nearly 30 years
- The principle application has been to detect the passage of ionising radiation with high <u>spatial</u> resolution and good efficiency.
- Segmentation → position
   Depletion depth → efficiency
- ( $W_{\text{Depletion}} = \{2\rho\mu\epsilon(V_{\text{ext}} + V_{\text{bi}})\}^{\frac{1}{2}}$ )

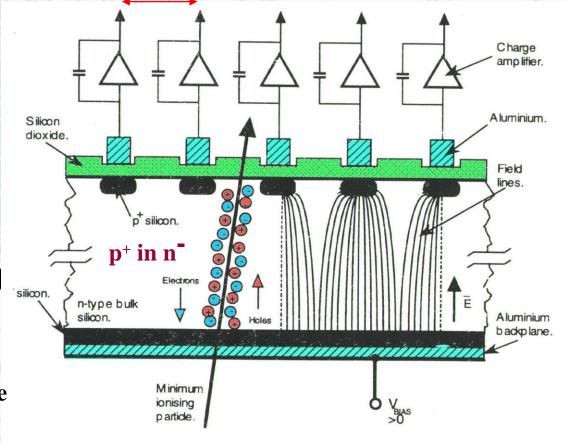
Resistivity

Applied Voltage

~80e/h pairs/µm produced by passage of minimum ionising particle, 'mip'

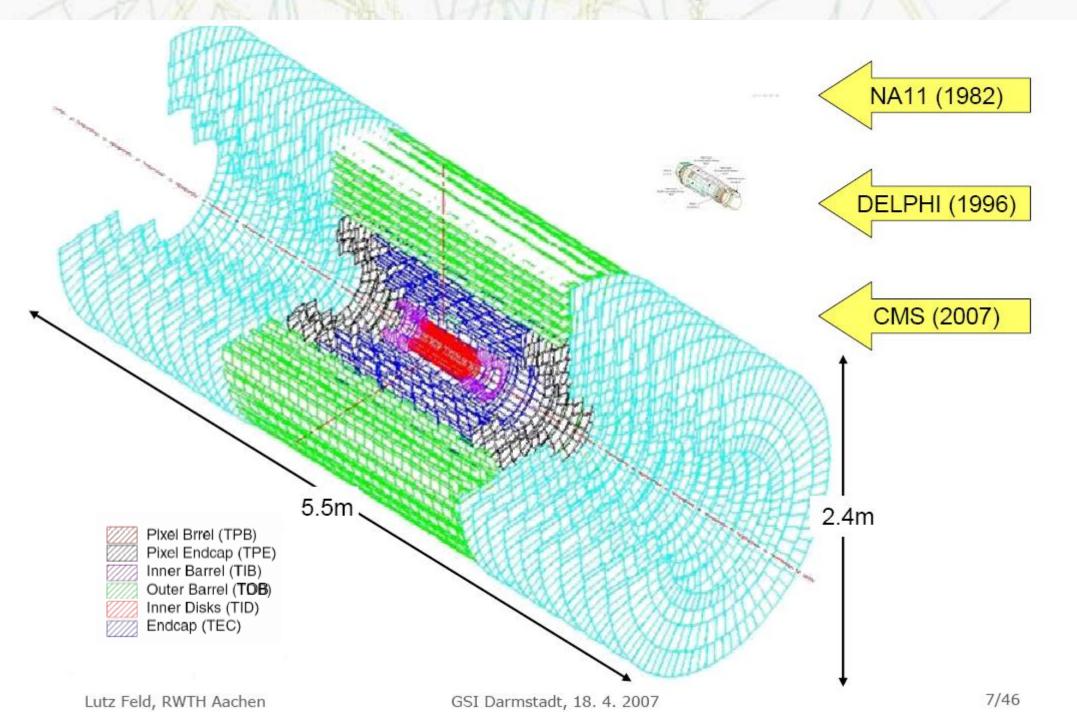
Mobility

Pitch ~ 50µm



Resolution ~  $5\mu m$ 

## **CMS Silicon Tracker: Largest Ever Built**



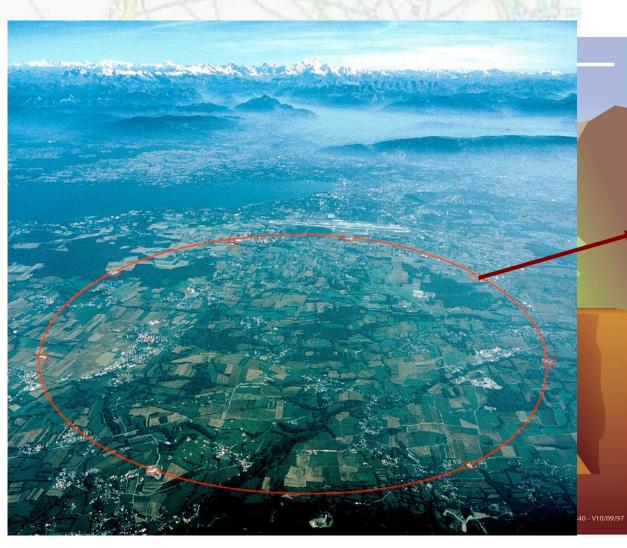
## **Experiments at the LHC**

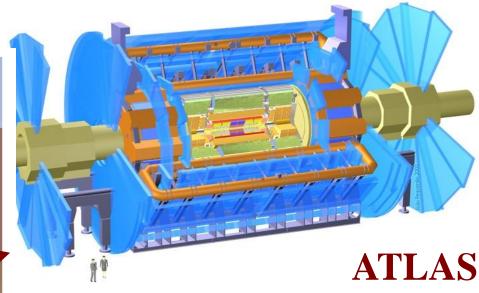
### **Collider Experiments**

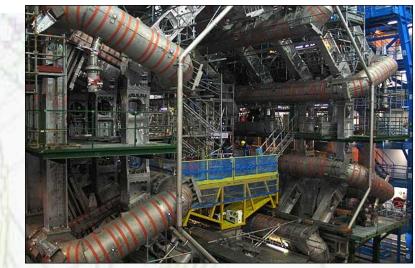
The other Giant General Purpose Detector at the LHC

**CERN Geneva** 

The Large Hadron Collider 14 TeV: Proton on Proton







## **Experiments at the LHC**

#### **Building 40 at CERN**



### • ATLAS, CMS, ALICE and LHCb

Detector Technologies

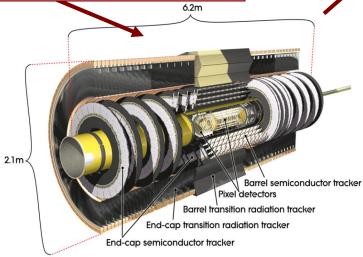
Noble gases, scintillators, crystals, Cherenkov, …

- Silicon Micro-strip Tracking Detectors

## **ATLAS Silicon Detector Tracker**

2112 Barrel and 1976 End-Cap Double-Sided Modules

61m<sup>2</sup> of silicon micro-strip detectors ~20,000 separate sensors ordered



**Barrel Ar** 



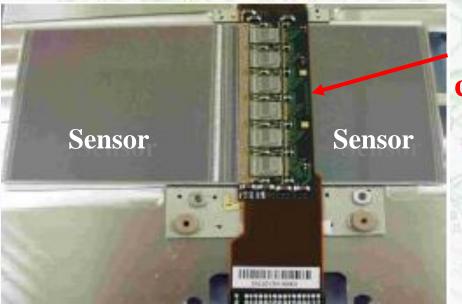
**ATLAS** 

## **ATLAS SCT Module Designs**

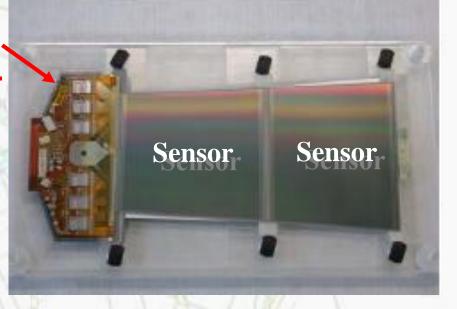
**ATLAS Tracker Based on Barrel and Disc Supports** 



Effectively two styles of double-sided modules (2 6cm long) each sensor ~6cm wide (768 strips of 80µm pitch per side)

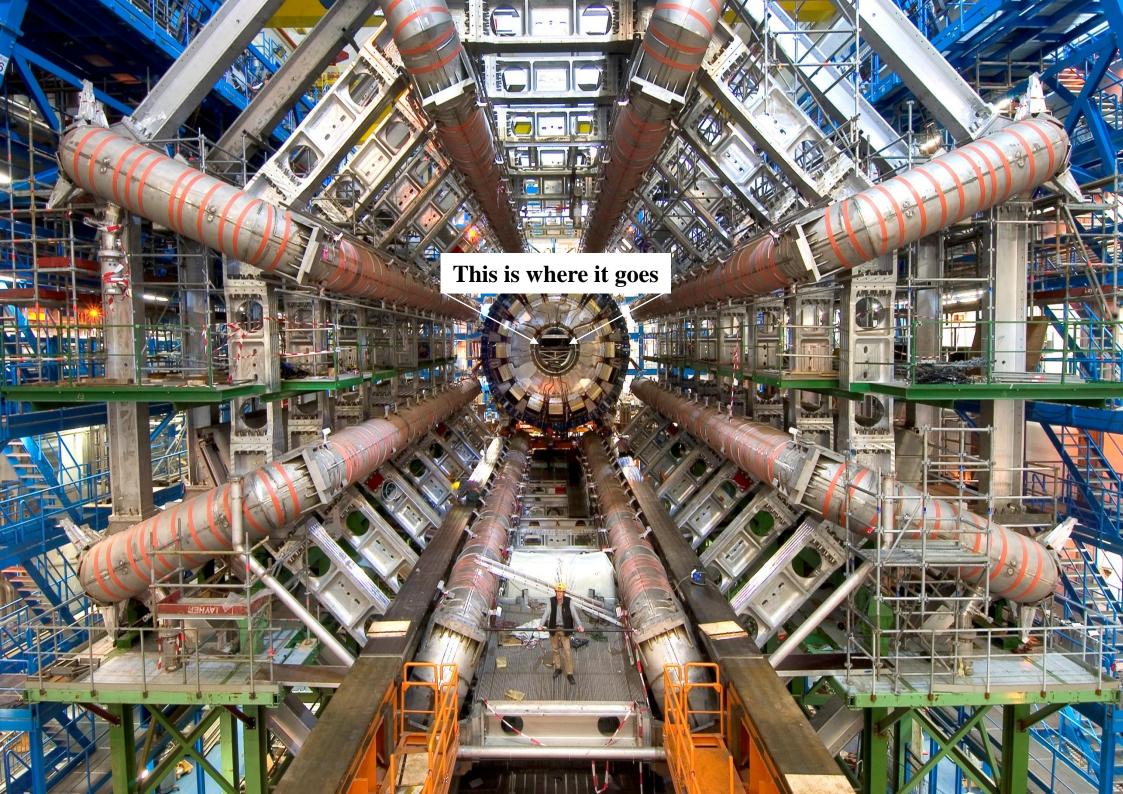


Hybrid cards, carrying readout chips and multilayer interconnect circuit



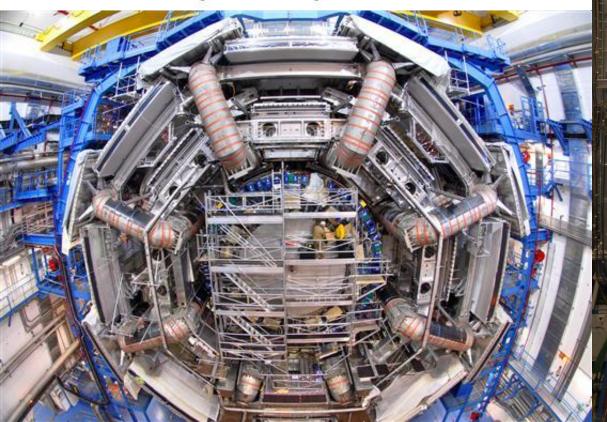
Barrel Modules (Hybrid bridge above sensors)

Forward Modules (Hybrid at module end)



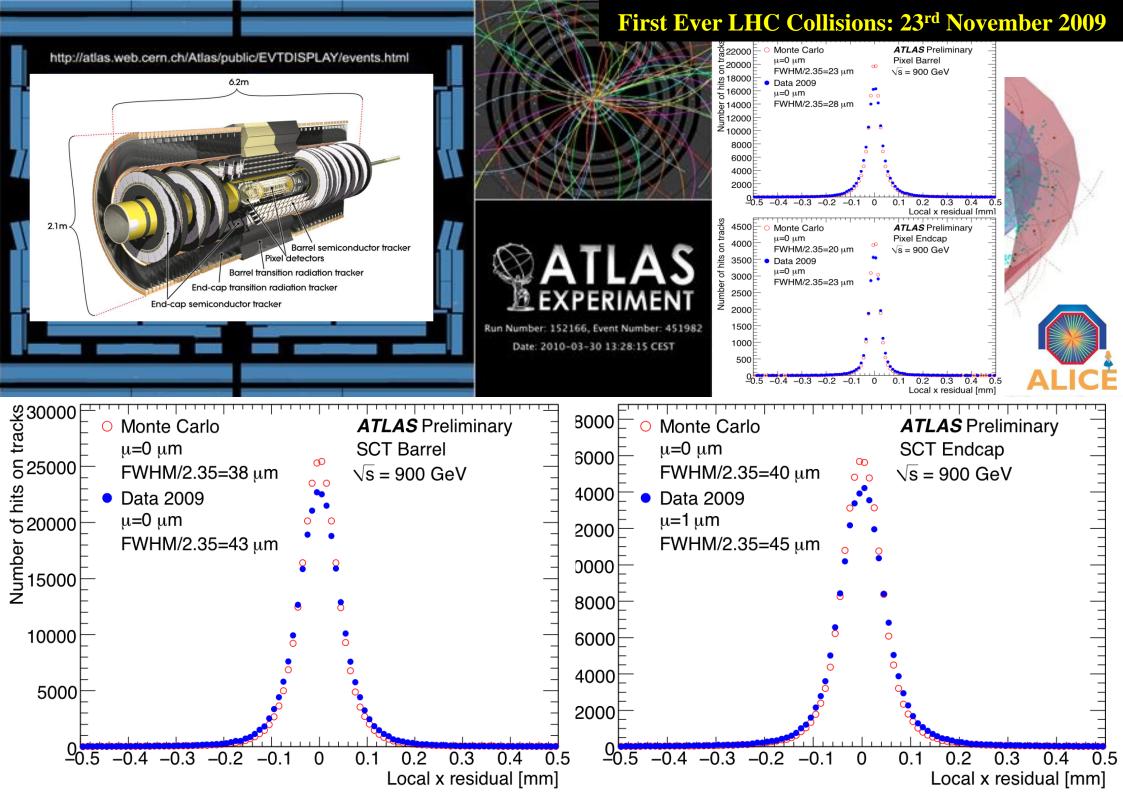


Liquid Argon Calorimeter



**Muon Detectors** 

Tile Calorimeter

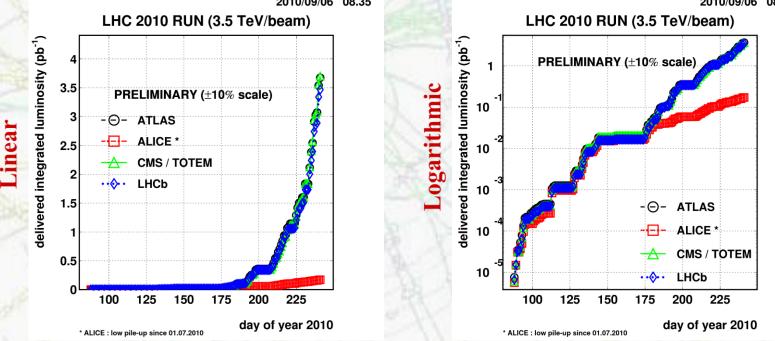


## **LHC Machine Performance in 2010**

"Luminosity" measured in units of b<sup>-1</sup> per second (or cm<sup>-2</sup>s<sup>-1</sup>) since this multiplied by  $\sigma$  gives event rate 1b (barn) is 10<sup>-28</sup>m<sup>2</sup> or 100 fm<sup>2</sup>

Cross-section ( $\sigma$ ) is a measure of the probability of a process per flux of incoming particles, so if luminosity,  $\mathcal{L}$ , represents the flux as seen be all the protons in one beam of oncoming protons in the other, this multiplied by the total cross-section,  $\sigma_{pp}$ , is the total event rate.

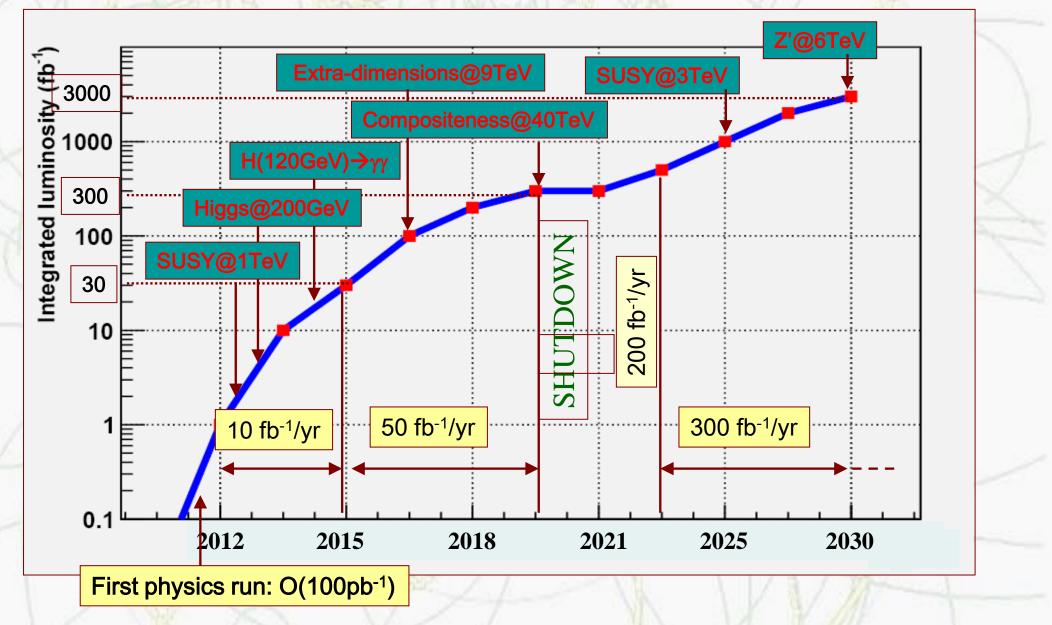
For sub-processes, the idea of a cross-section can still be used to give the event rate for that sub-process when multiplied by *L* 



The design number of protons per bunch,  $1.1 \ge 10^{11}$ , was first achieved  $10^{th}$  June 2010 and is now routine. The emphasis now is to increase the number of bunches circulating at any time in the LHC and then to further improve the final focus. Record luminosity: ~ 4  $\ge 10^{31}$  cm<sup>-2</sup>s<sup>-1</sup> achieved 24<sup>th</sup> September

### **Examples of Possible ATLAS/CMS Physics Reach by Year**

("Integrated Luminosity" is luminosity × time and is a measure of number of total number of events )



## **Experiments at the LHC**

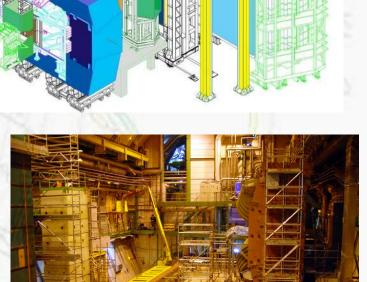
#### **Collider Experiments**

Charles and the second



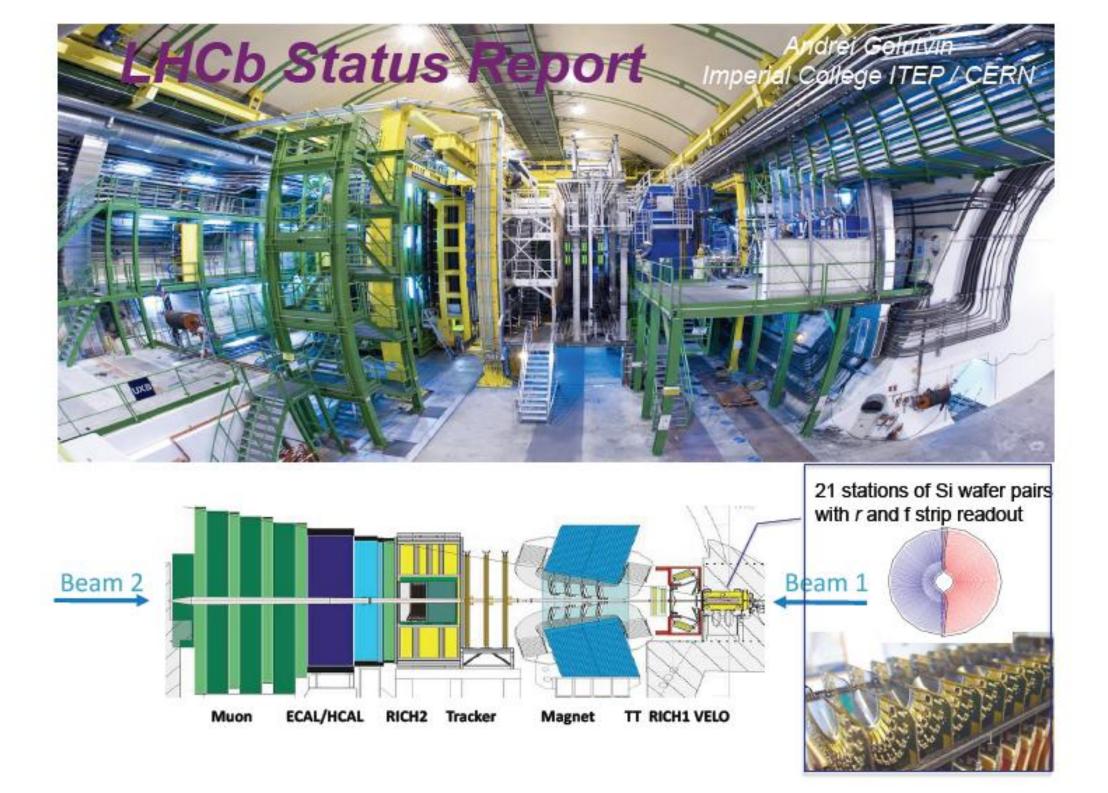
High Statistics B Physics

Sensitivity to new physics through being sensitive to subtle effects or rare phenomena



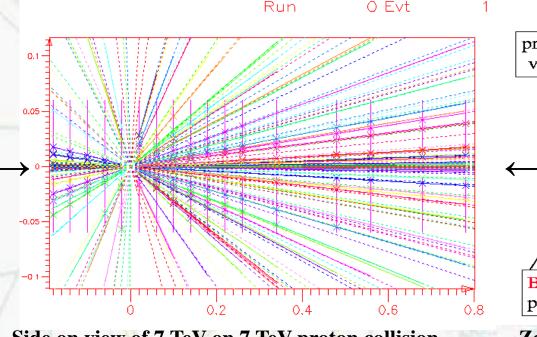
LHC

**Complementary physics reach to ATLAS and CMS** 

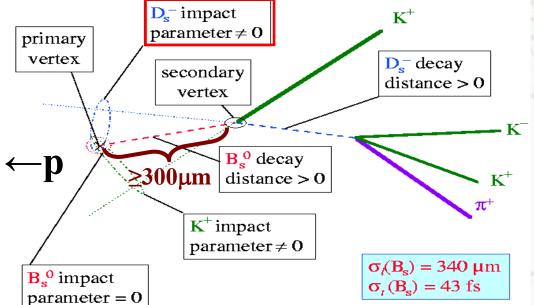


## **B-tagging with Highly Segmented Detectors**

- Nearly all early applications of silicon micro-strip detectors were to detect and measure particles with pico-second (10<sup>-12</sup>) lifetimes such that (taking account of special relativity)  $\beta\gamma c\tau \ge 300 \mu m$
- This meant the primary goal was to locate primary (collision) and secondary vertices (as is the case in LHCb)





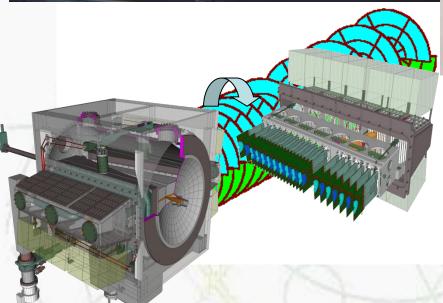


Zoom in showing just particles from B<sub>S</sub>-meson decay

In all four major LHC experiments silicon used for vertexing and as primary charged particle tracking detectors for highest radiation environments

## **LHCb Vertex Locator Modules**

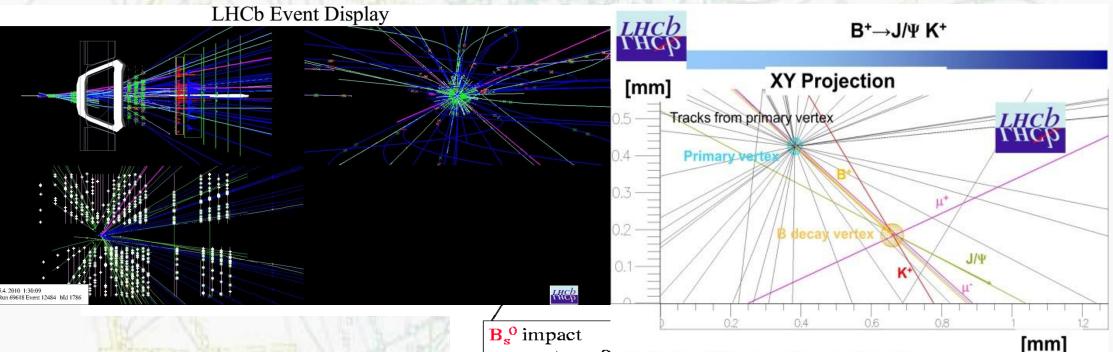




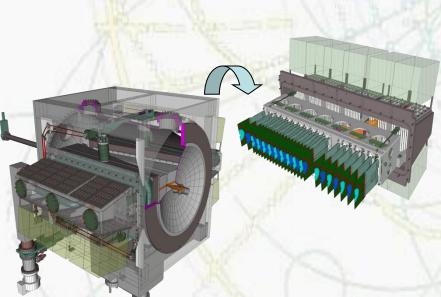
At the LHC B-mesons are mostly produced in pairs going predominantly near the beam axis (forward region) LHCb will collect up to 10<sup>12</sup> b-pairs /year and the detector is optimized to study B-mesons

B decays are identified using the fact that their lifetime of 10<sup>-12</sup> s makes it possible (with accurate enough tracking) to see that some tracks come from a displaced vertex.

## **LHCb Vertex Locator: First B Event**



parameter = 0



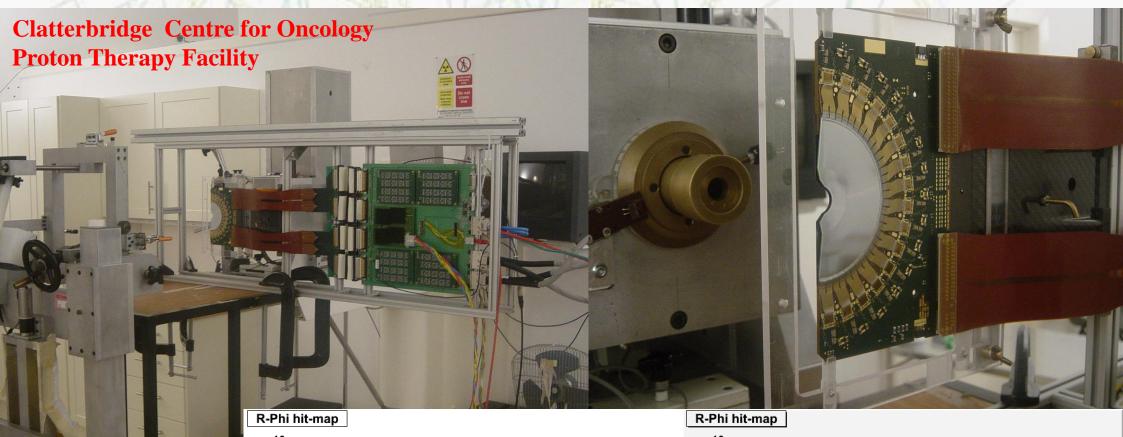
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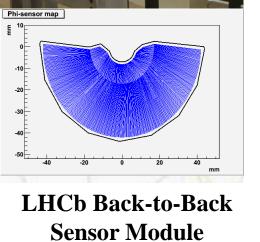
Tracks from PV are forced to come from PV

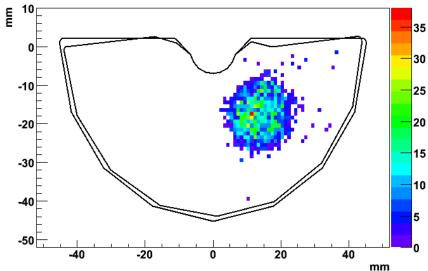


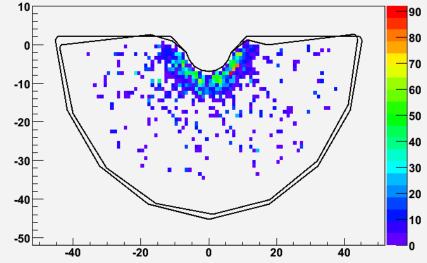


## **LHCb Vertex Locator: Other Uses**









# LHCb Upgrade schedule

### □ Phase I: 2016 LHC long shutdown

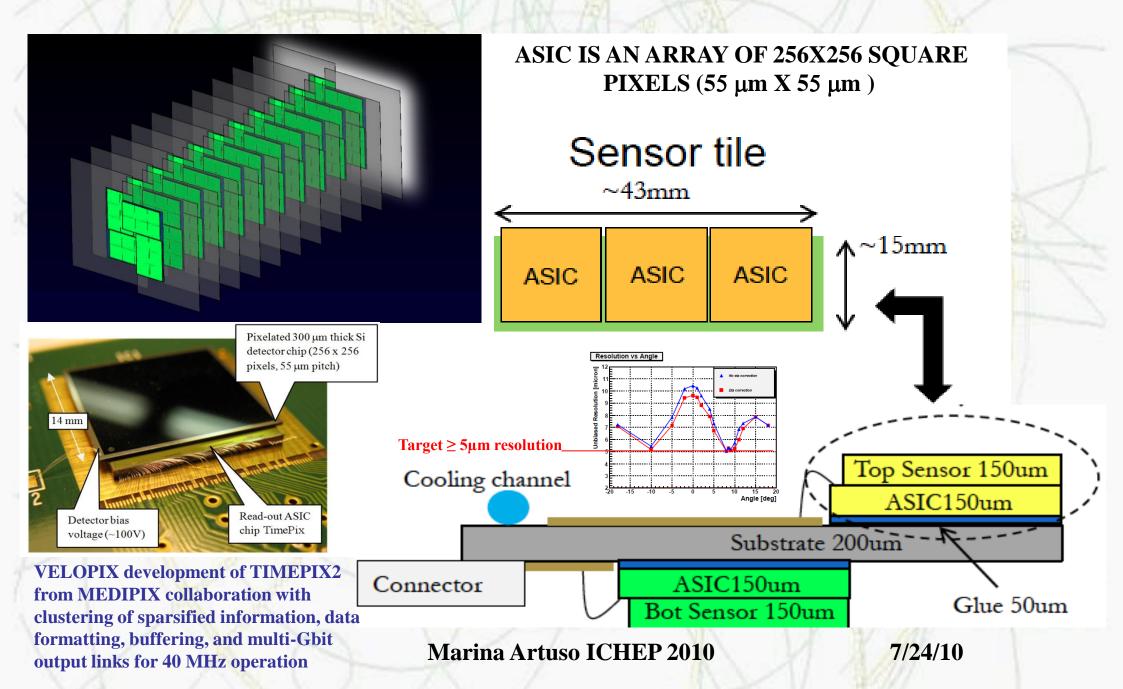
- Novel pixel based vertex detector (VELOPIX)
- New front end electronics
- New trigger and data acquisition concept to achieve better efficiency for hadronic B decays
- RICH photon detector replacement
- New track trigger and inner tracker triggering systems

Phase II: 2020 LHC shutdown for luminosity upgrade
 new hadron ID system based on precision time of flight
 Better electromagnetic calorimeter segmentation
 Change to inner and outer tracking geometry

Marina Artuso ICHEP 2010

7/24/10

# LHCb VELO PIXEL Upgrade





Hadron Au
Collider Har
Physics
Symposium

August 23-27, 2010 University of Toronto, Toronto, Canada

> Rene Bellwied Wayne State University

Outline: •Motivation •Machine upgrades •Luminosity upgrades •Detector upgrades •Future of heavy ions HCP 2010, TORONTO



# Inner Tracking System upgrade

## Present 6 detector layers based on three silicon

technologies:

- SPD (Si pixels)
- SDD (Si Drift)
- SSD (Si strips)
- Unique levelzero trigger (fast OR)

Optimize pixel material budget: ~1.1% X<sub>0</sub> per layer

> Carbon fibre: 200 µm Cooling tube (Phynox): 40 µm wall thickness Grounding foil (Al-Kapton): 75 µm Pixel chip (Silicon): 150 µm Bump bonds (Pb-Sn): diameter ~15-20 µm

Silicor sensor: 200 µm Pixel Los <u>(Al+Kapton</u>): 280 µm SMD components Gluc , 2ccobond 45) and thermal

Radii: 4, 7, 15, 24, 39, and 44 cm Total material budget of 7%X<sub>0</sub> (normal incidence) Pixel size 50 μm times 425 μm Beam pipe radius 2.98 cm

8/27/2010

HCP 2010, TORONTO 20/31

LHC beam

interaction

Sept. 12, 2008



# Inner Tracking System upgrade

Improving the impact parameter resolution by a factor two or better will:

- increase sensitivity to charm by factor 100;
- give access to charmed baryons (baryon/meson ratio in charm sector to test recombination);
- allow study of exclusive B decays;
- allows first measurement of total B production cross section down to zero P<sub>T</sub>;
- Improve flavour tagging.



## **Monolithic Pixel Detectors**

Goal: a monolithic detector in standard very deep submicron CMOS technology

Advantages: cost, material budget (50 um thickness), yield, low noise, high granularity (10x10 um), radiation hard, low power consumption (20 mW/cm<sup>2</sup>)

Disadvantages: Charge collection by drift, serial readout

#### R&D activities: MIMOSA and LePix

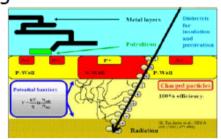
- LePix: : non-standard processing on high resistivity substrate
- Advanced CMOS deep submicron technologies (130 nm and beyond) can be implemented on  ${\geq}100~\Omega cm$  (~  $30\mu m$  depletion at 100 V)

•MIMOSA: 'traditional' monolithic detectors, MAPS-based with serial readout

- P-type low-resistivity Si hosting n-type "charge collectors"
  - signal created in epitaxial layer (low doping)

Q ~ 80 e-h/mm  $\rightarrow$  signal  $\leq$  1000 e<sup>-</sup>

- charge sensing through n-well/p-epi junction
- -excess carriers propagate (thermally) to diode



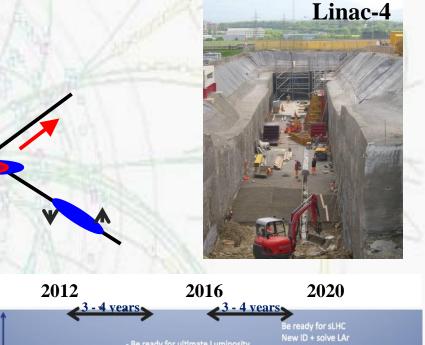
- Prototype: MIMOSA-22, binary output, integrated zero-suppression, 18.4  $\mu m$  pitch, 1152 columns x 576 rows, ~110  $\mu s$  readout time

#### R. BELLWIED

8/27/2010

## **Upgrading the LHC for High Luminosity**

- With modest investment, the LHC can run at **much higher collision rates**, greatly increasing the scope to search for new particles and study rare processes
- Expected Development in Luminosity
  - Phase-I (after 5 years)
    - Up to ~ 60fb<sup>-1</sup>/year
    - Experiments need:
      - New vertex detectors
      - New off-line electronics
  - Phase-II (after 10 years)
    - Up to ~ 300fb<sup>-1</sup>/year
    - Experiments need:
      - Complete tracker replacement
      - Much improved on-line filtering
      - New read-out for many subsystems





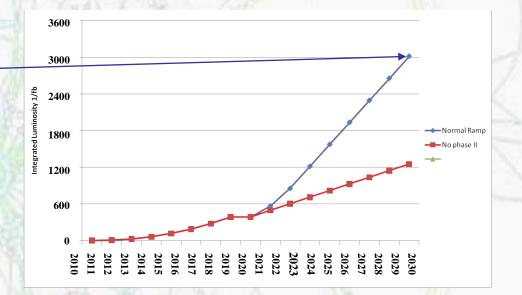
#### Shutdown requirements :

Phase-0: 12-14 months (defined by the LHC consolidation) Phase-1: 8-9 months (time necessary to install at least the new pixel b-layer) Phase=2-P18=20 months to install and debug the new ID detector

## **Upgrading the Experiments**

To keep ATLAS and CMS running beyond ~10 years requires tracker replacement Current trackers designed to survive up to 10Mrad in strip detectors (≤700 fb<sup>-1</sup>) For the luminosity-upgrade the new trackers will have to cope with:

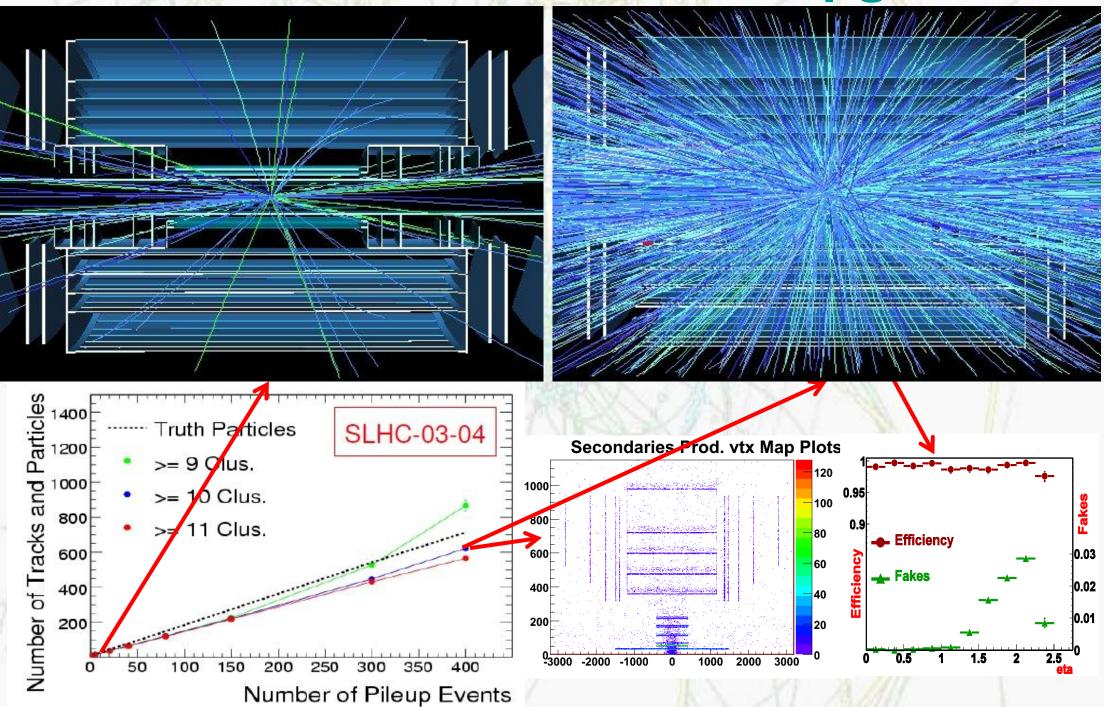
- much higher integrated doses (need to plan for ≥ 3000 fb<sup>-1</sup>)\_\_\_\_
- much higher occupancy levels (up to 400 collisions per beam crossing)
- Installation inside an existing 4π coverage experiment



Budgets are likely to be such that replacement trackers, while needing higher performance to cope with the extreme environment, cannot cost more than the ones they replace

**To install a new tracker in ~2020, require Technical Design Report 2014/15** (Note the ATLAS Tracker TDR: April 1997; CMS Tracker TDR: April 1998)

## **ATLAS All-Silicon Tracker Upgrade**

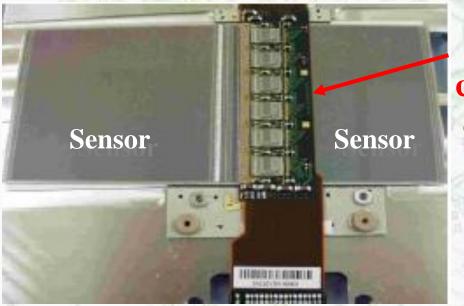


## **Current SCT ATLAS Module Designs**

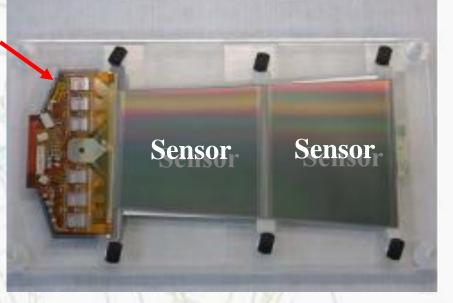
**ATLAS Tracker Based on Barrel and Disc Supports** 



Effectively two styles of double-sided modules (2 6cm long) each sensor ~6cm wide (768 strips of 80µm pitch per side)



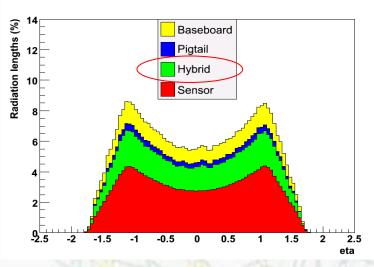
Hybrid cards, carrying readout chips and multilayer interconnect circuit



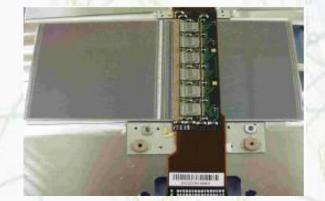
Barrel Modules (Hybrid bridge above sensors)

Forward Modules (Hybrid at module end)

# **Current Silicon Microstrip (SCT) Material**



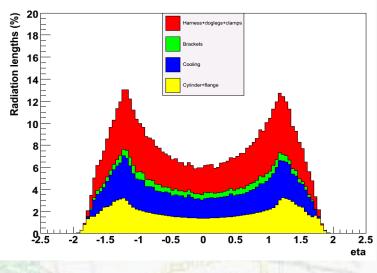
Old ATLAS Barrel Module 12 ASIC of 300µm thickness for double-sided module read-out (*ie* just 6 read-out chips per side)



New ATLAS sLHC-Tracker Module will have 80 ASICs in two hybrid fingers for just one-sided read-out Current Silicon Tracker (4 barrel strip layers)



Table 1



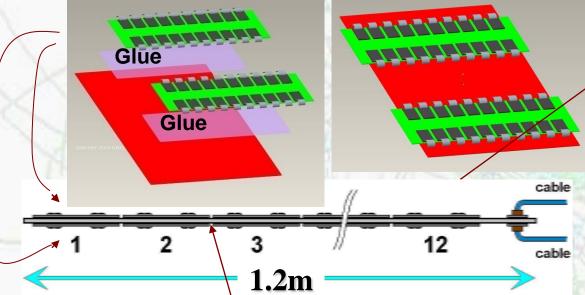
#### "The barrel modules of the ATLAS semiconductor tracker". Nucl.Instrum.Meth.A568:642-671,2006.

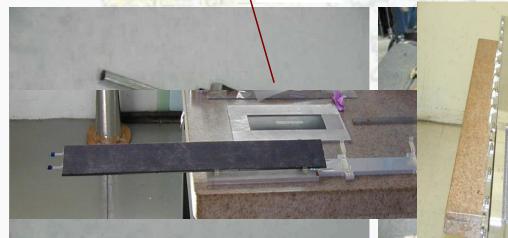
Radiation lengths and weights estimated for the SCT barrel module

Component	Radiation length [%Xo]	Weight [gr]	Fraction [%]
Silicon sensors and adhesives	0.612	10.9	44
Baseboard and BeO facings	0.194	6.7	27
ASIC's and adhesives	0.063	1.0	4
Cu/Polyimide/CC hybrid	0.221	4.7	19
Surface mount components	0.076	1.6	6
Total	1.17	24.9	100

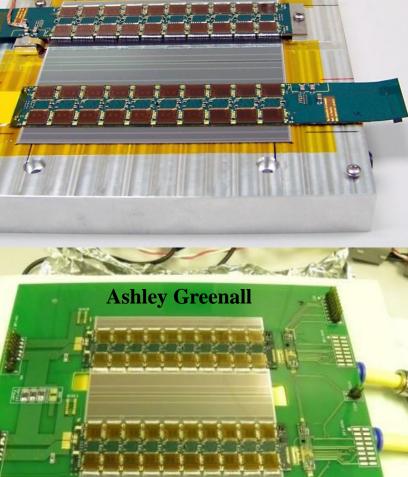
Hybrid area per module roughly 2 at sLHC - much higher R/O granularity

# Stave: Hybrids glued to Sensors glued to Bus Tape glued to Cooling Substrate





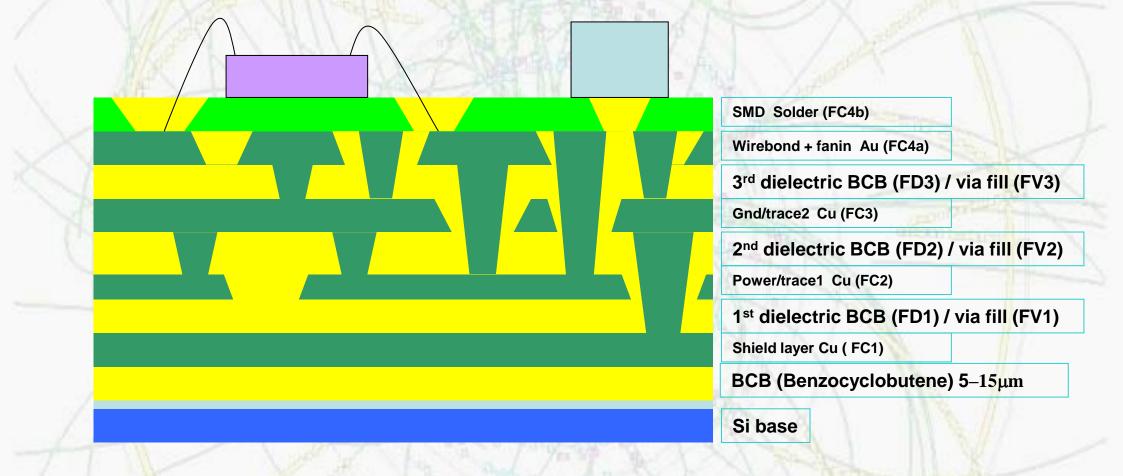
LBNL, BNL, Yale, Oxford



he University of Liverpool

#### **Direct Processing of Hybrid Circuit on Silicon Sensor**

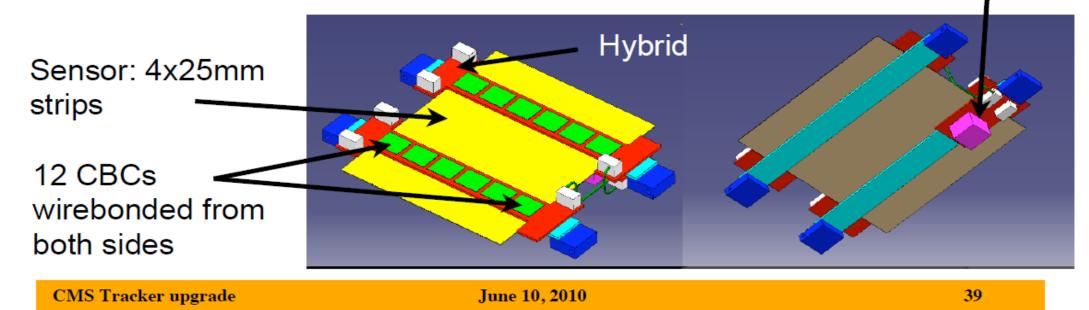
(Ultimate reduction in mass and assembly complexity.)



**Does away with need for hybrid substrate and thick-film processing. Prototyping for ATLAS underway with several European manufacturers.** 

## CMS Tracker Replacement Module Concept

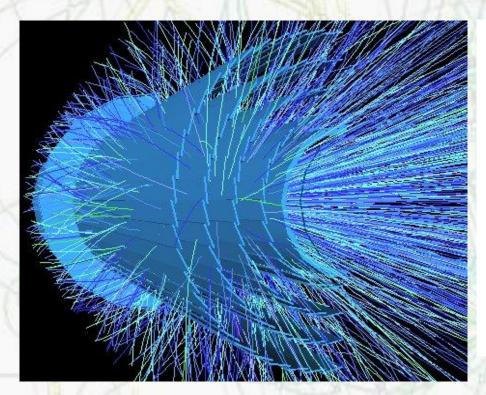
- Front end ASIC going to submission: CBC
  - Evolution of APV25
  - 130nm technology
  - Binary non-sparsified readout
  - Low power (<0.5mW/channel)
  - Optimised for 25 to 50 mm strips
- First module/ladder concept developed

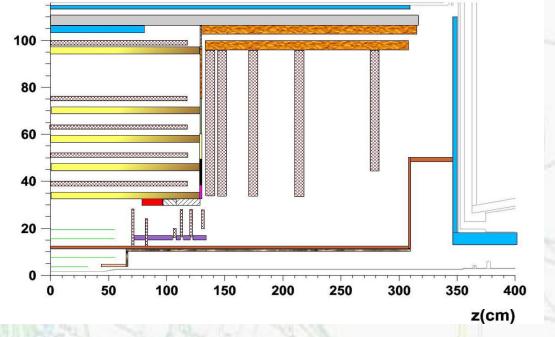


DC/DC

converter

## **Radiation Background Simulation**





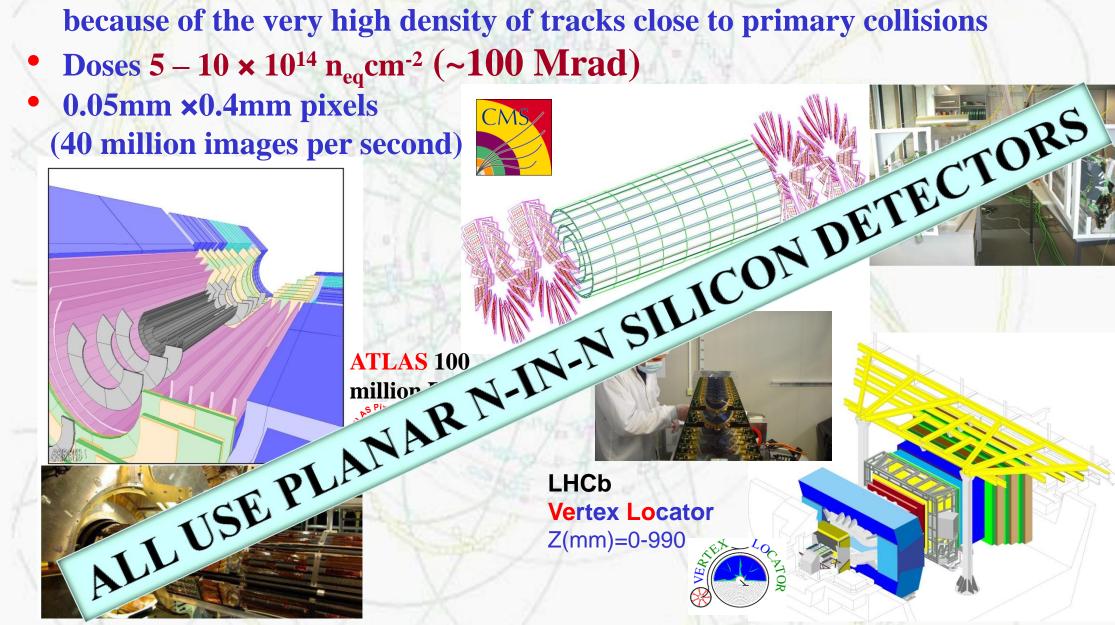


#### At inner pixel radii - target survival to 1-2×10<sup>16</sup> n<sub>eq</sub>/cm<sup>2</sup>

4.4x10^14 4.9x10^14		0 <sup>17</sup>
<sup> 1.8x10^14</sup> For strips 3000fb <sup>-1</sup>		<b>0</b> <sup>16</sup>
		J
6.1x10 <sup>14</sup> required up to		0 <sup>15</sup>
$4.4x10^{14}$ ~1.3×10 <sup>13</sup> $n_{eq}$ /cm <sup>2</sup>	20	
		<b>0</b> <sup>14</sup>
3.0x10^14 2.7x10^14	0 50 100 150 200 250 300 350 400	
1	4.9x10^14 1.6x10^14 1.8x10^14 6.0x10^14 6.0x10^14 5.8x10^14 6.1x10^14 5.8x10^14 4.4x10^14 3.0x10^14 <b>For strips 3000fb<sup>-1</sup> <math>\times 2</math> implies survival required up to <math>\sim 1.3 \times 10^{15} n_{eq}/cm^2</math></b>	$\begin{array}{c} 100 \\ 4.9x10^{14} \\ 1.6x10^{14} \\ 1.8x10^{14} \\ 6.2x10^{14} \\ 6.2x10^{14} \\ 6.2x10^{14} \\ 5.8x10^{14} \\ 6.1x10^{14} \\ 5.8x10^{14} \\ 71.3 \times 10^{15} n_{eq}/cm^2 \\ 3.0x10^{14} \end{array}$

## **Technology in Current Highest Dose Regions**

- LHC vertex detectors closes to the interaction point:
- Required to be very radiation hard and to be very finely segmented because of the very high density of tracks close to primary collisions



# **Motivations for P-type Silicon Wafers**

### Starting with a p<sup>-</sup>-type substrate offers the advantages of single-sided

processing while keeping n<sup>+</sup>-side read-out:

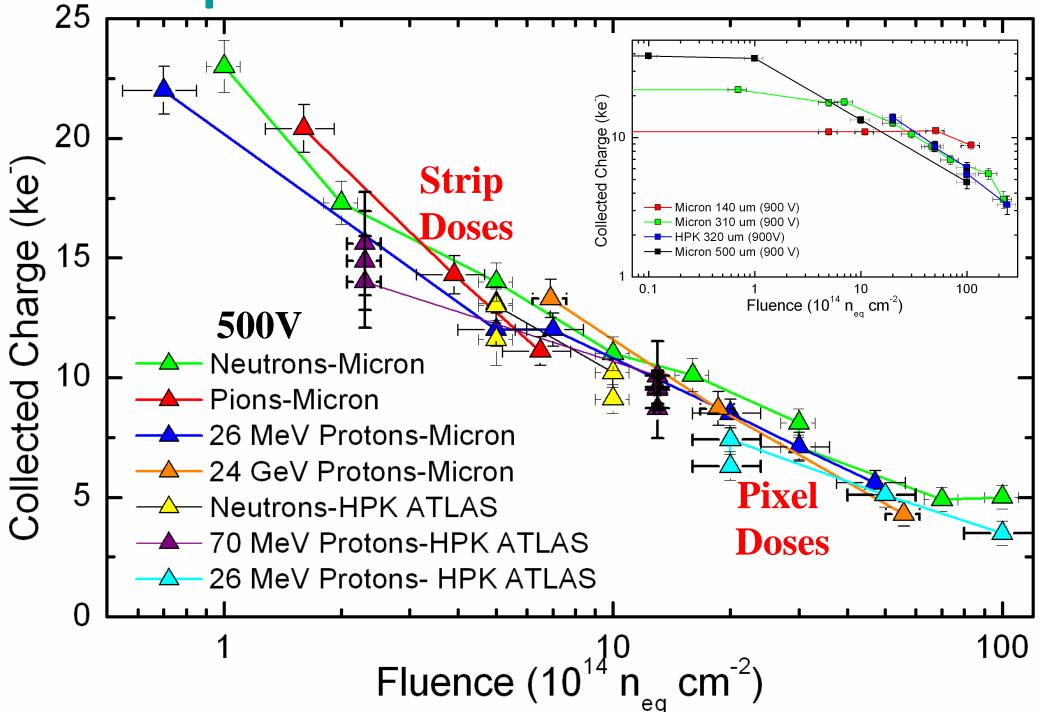
- Processing Costs (~50% cheaper).
- Greater potential choice of suppliers.
- High fields always on the same side.
- Easy of handling during testing.
- No delicate back-side implanted structures to be considered in module design or mechanical assembly.

So far, capacitively coupled, polysilicon biased p-type devices fabricated to ATLAS provided mask designs by:

- Micron Semiconductor (UK) Ltd
- CiS Erfurt (Germany)
- CNM Barcelona (Spain)
- ITC Trento (Italy)
- Hamamatsu Photonics HPK (Japan) (Including full-size 10cm ×10cm prototype)



## n-in-p Planar FZ Sensor Irradiations



Gianluigi Casse and Tony Affolder,

## **Alternative Technologies to Planar Silicon**

**3D Sensors with Doped Through Silicon Columns** 

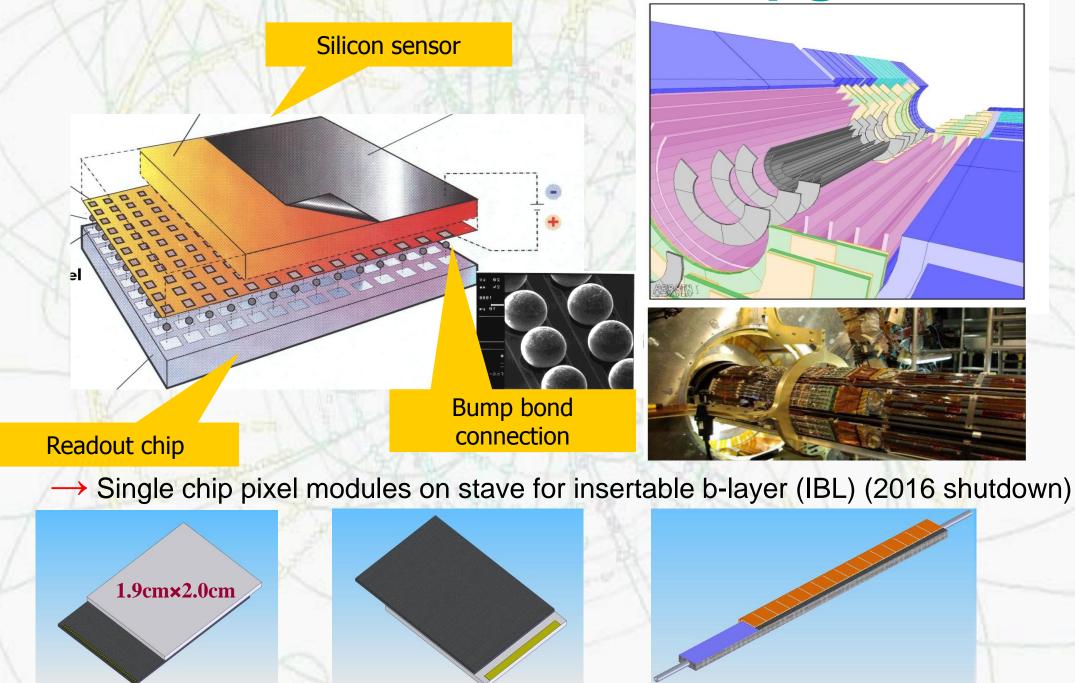
Double Side Double Type Column Signal of the channel closest to the track point of impact unirradiated, 70 V irradiated ( $1x10^{15} n_{r}/cm^{2}$ ), 200 V 2200E d 1000 2000⊢ 1800 800 1600 1400 1200 Eutrie Entries 600 D 800 400 600È 400 200 200 FBK/IRST:completed a FE-I3 run. Full 3D in the -20 0 -20 20 40 80 100 120 140 160 180 0 60 20 40 60 80 100 120 140 160 180 -0 next run. Signal (ADC counts) Signal (ADC counts) · CNM: being completed and bump bonded to BURG Higher signal after irradiation than before Planar CVD Diamond: Poly-crystalline or Single Crystal  $\rightarrow$  Charge multiplication! **Preliminary Summary of Proton Irradiations** (mn) 500 Entries at low signal values: charge sharing, tracks going straight 450 through columns ė distan 400 Red Data: strip scCVD (x-shifted by -3.8) Leakage current, -10°C, 10<sup>16</sup> n<sub>eq</sub>/cm<sup>2</sup> V<sub>bias</sub> fixed at 150V Open Red: pixel scCVD (x-shifted by -3.2) 350 25000 **Trap-to-band tunnelling** collection Blue Data: strip pCVD e 1E-5 University of Glasgow 300 **Impact** ionisation 20000 Charge Strip current at -10°C (A) 250 Blue curve: ccd=ccd0/[1+k\*phi\*ccd0] 15000 time (mi 200 chards 150 chards 1E-6 Collected 10000 15 5000 Charge multiplication 60 100 - 240 . 480 50 Annealing time 960 12 10 1920 0 100 200 300 400 Fluence /  $10^{15}$  (1 MeV  $n_{eq}$  cm<sup>-2</sup>) 10 15 20 5 25 n Vbias (V)

Hamburg/EVO, April 21, 2010

Marko Mikuž: Small radius pixel sensors

Irradiation (x10^15 p/cm^2)

# **ATLAS Pixel Module Upgrade**

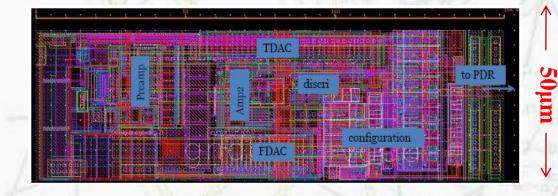


# **ATLAS Pixel Upgrade ASIC**

- New Front-End chip (FE-I4) for smaller pixel dimensions being delivered
  - Fabricated for Phase-I b-layer replacement (IBL)

 $\rightarrow$  an intermediate step towards the full upgrade. Performance improvements for the detector (issues more related to FE chip):

- Reduce radius → Improve radiation hardness planar , 3D sensors, diamond, gas, …?)
- Reduce pixel cell size and architecture related dead time
  - $(\rightarrow \text{ deign FE using 0.13 } \mu \text{m 8 metal CMOS})$
  - increase the module live fraction
    - → increase chip size, 19×20 mm<sup>2</sup>

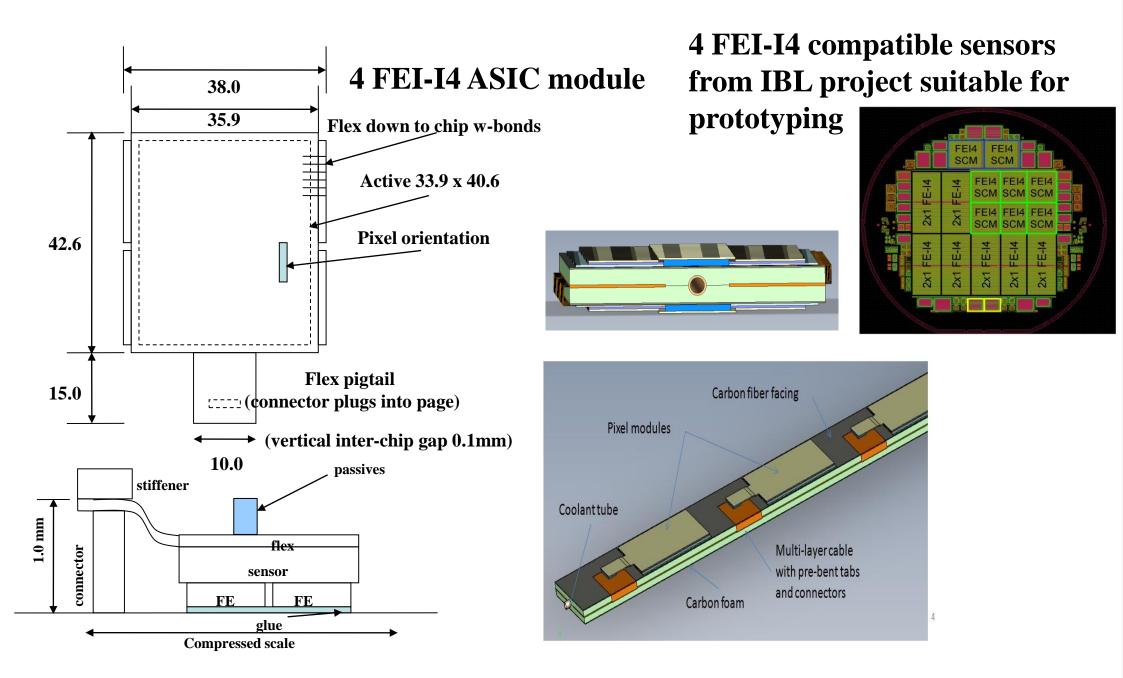


250µm

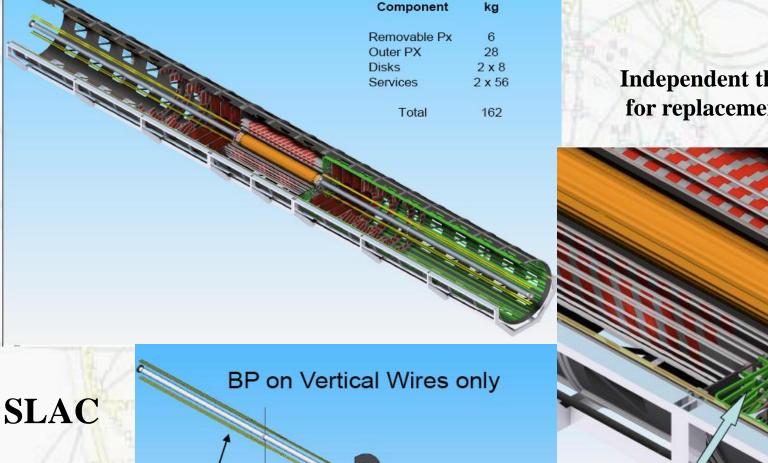
**Main Parameter** Value Unit Pixel size 50 x 250  $\mu m^2$ DC-coupled negative Input polarity Normal pixel input 300÷500 fF capacitance range In-time threshold 4000 e with 20ns gate Two-hit time 400 ns resolution DC leakage current 100 nA tolerance Single channel ENC 300 e sigma (400fF) Tuned threshold 100 e dispersion Analog supply 10 μA current/pixel @400fF Radiation tolerance 200 **MR** ad Acquisition mode Data driven with time stamp Time stamp bits 8 precision Single chip data 160 Mb/s output rate

#### FE-I4 (B-layer Replacement) Specifications: main parameters

## **SLHC Phase-II Pixels Outer Layer Stave Concept**



# **Possible Phase-II Pixel Mechanics**



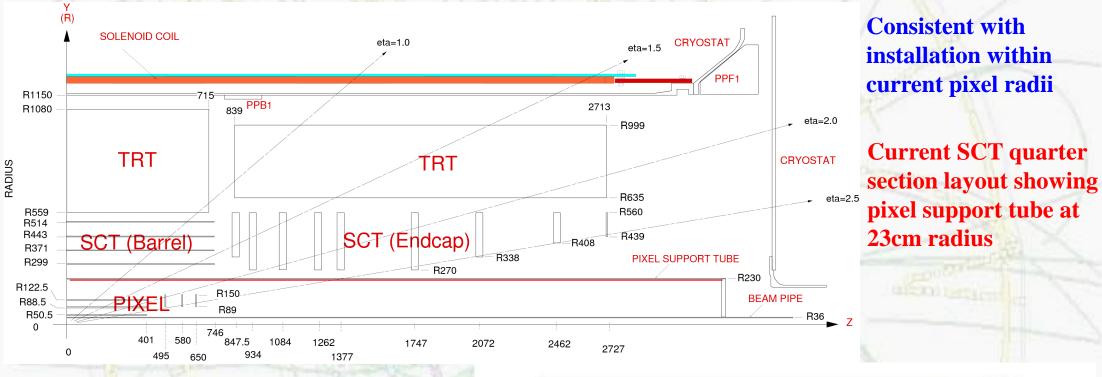
Independent thermal enclosure for replacement pixel package

Insertion rails

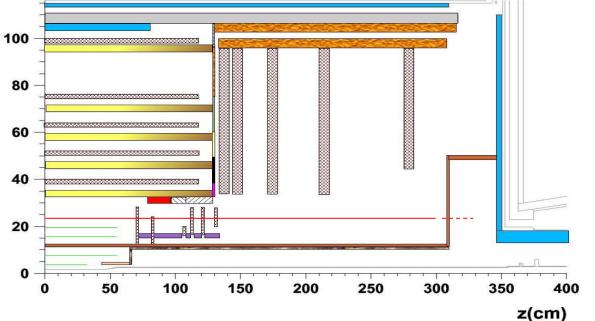
Insertion

**IBL remains separately insertable** 

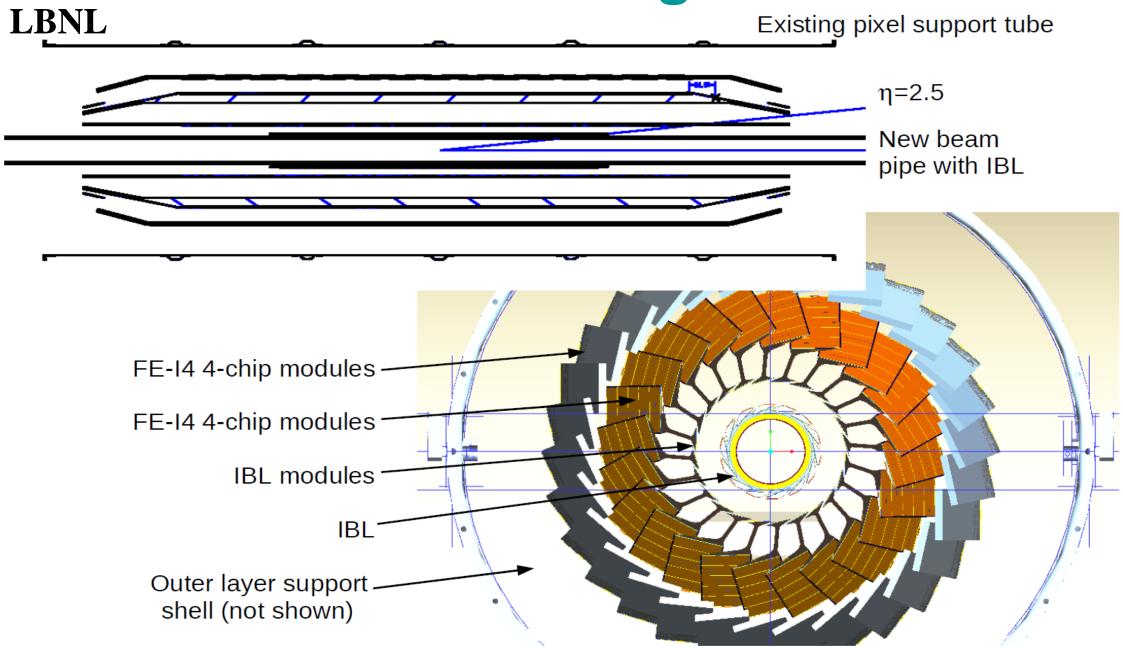
## **Independently Installable Pixels**



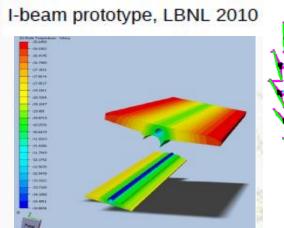
Proposed All-silicon tracker layout showing radius of current pixel support tube.

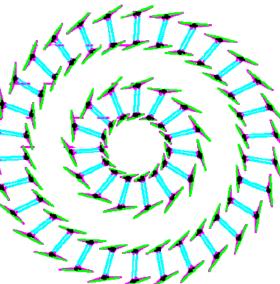


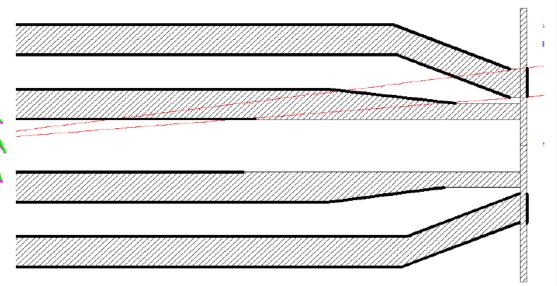
# Independently Installable Phase-II Pixel Design



# **Material Reduction**

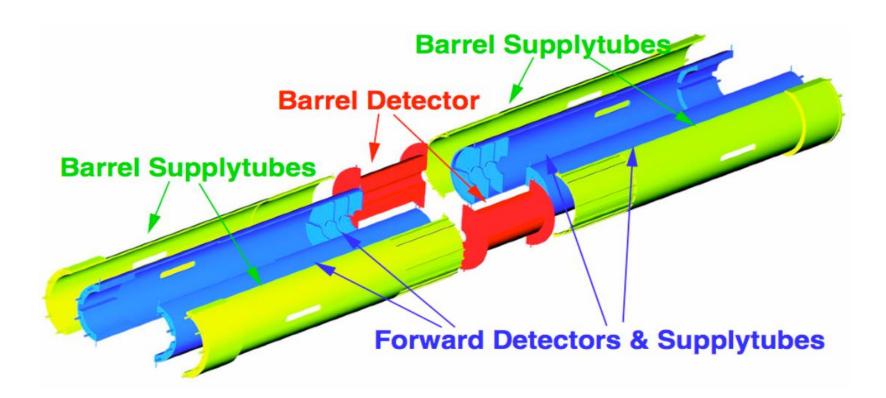






		Present detector + IBL	Double I-Beam
LBNL	Number of channels	92 M	276 M
	Global supports mass	8.3 kg	2.1 kg
	Local supports mass	6.6 kg	5.6 kg (meas.)
	Silicon mass equivalent of all mechanics	5.7 kg	2.8 kg
	Sensor + chip mass	2.9 kg	4.4 kg (*)
	Total silicon equivalent	8.7 kg	7.2 kg

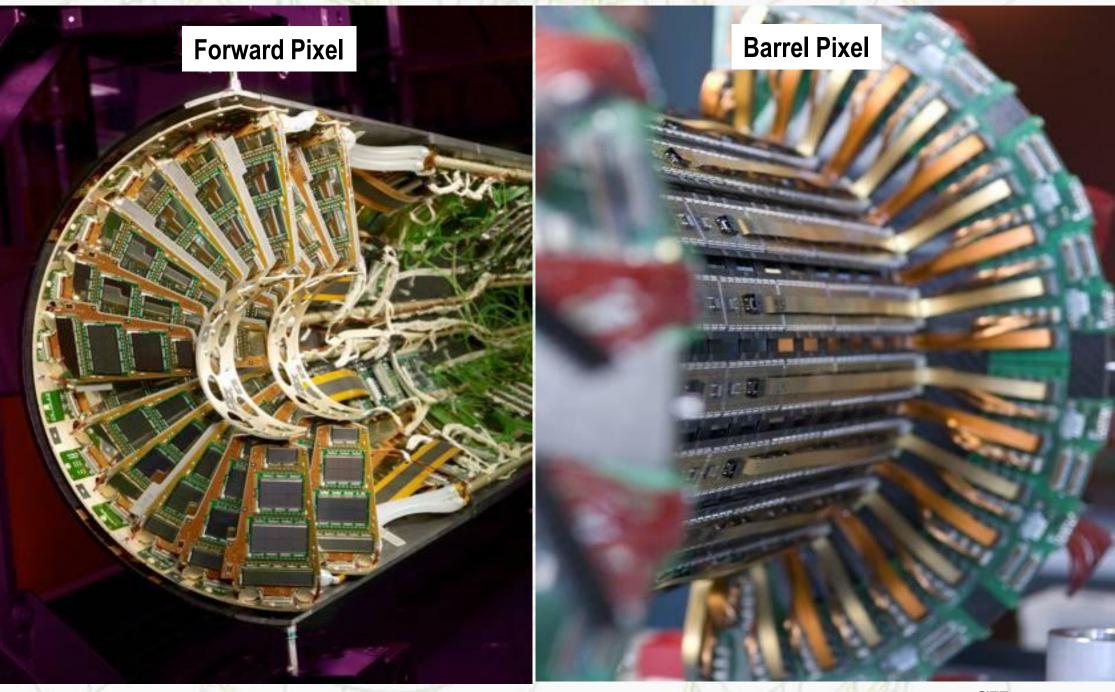
# **CMS** Pixel System



- Designed for fast insertion (beam pipe bake out)
- Will be done in regular shutdown
- Can be replaced by improved system

June 10, 2010

# **Current CMS Pixel Detector**



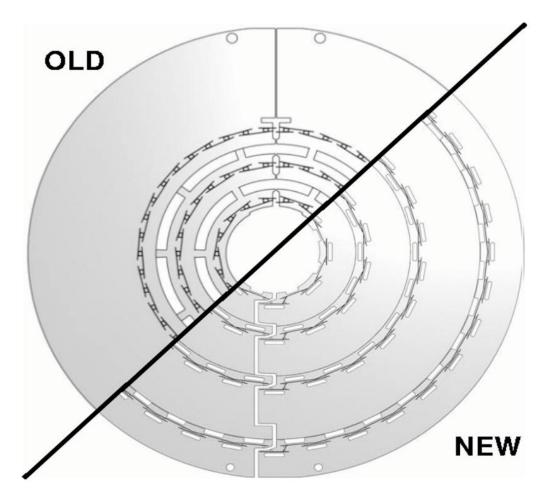
T. Rohe et al. Planar sensors for the upgrade of the CMS pixel detector, Pixel2020, Sep. 6-10, Grindelwald, CH

## Mechanics of Barrel

Add 4<sup>th</sup> layer :

- layers @ 39,68,109 & 160 mm
- beam pipe clearance 4 mm
- 8 modules along z (1216 total)
- 'ultra' light support structure

CO<sub>2</sub> based cooling system



# Mechanics of Disks

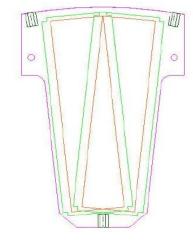
Inner & outer ring of blades

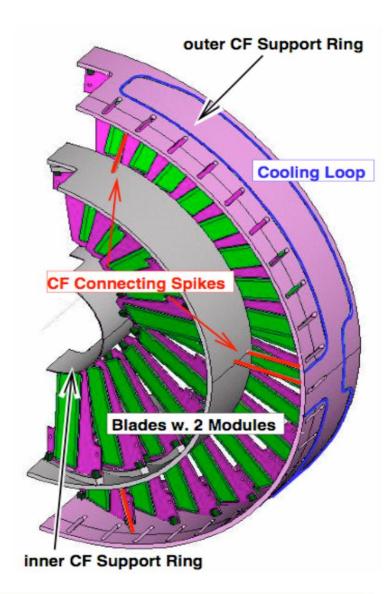
CO<sub>2</sub> tubes embedded in half disk support:

- support cylinder:
  - Carbon carbon
  - Grooves for cooling tube
  - Stainless steel tube:
  - 1.8mm OD, 100μm wall

Blades:

- all identical
- Rotated by 20° radial
- Tilted by 12° (inner ring)
- 2 modules per blade (φ overlap)
- individually replaceable

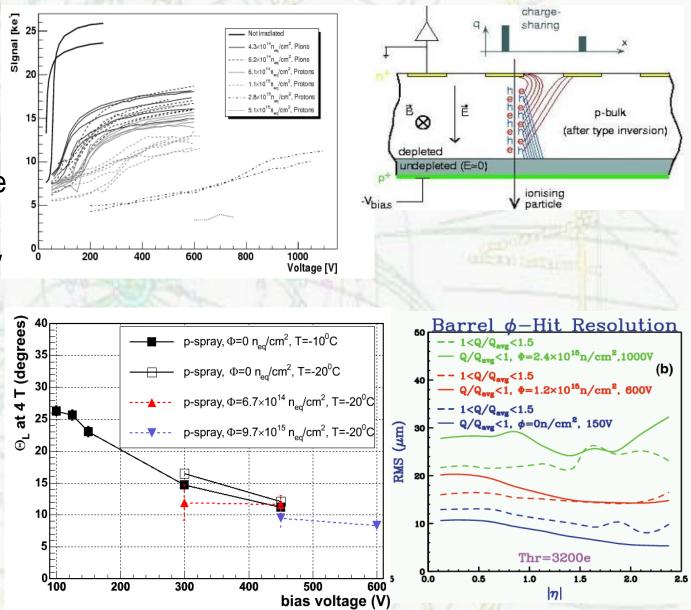




June 10, 2010

# **CMS Irradiation Results**

- Highly irradiated sensors operative up to 1kV
- No signal saturation with bias for  $\Phi > 2 \times 10^{15} n_{eq}/cm^2$ 
  - Is this a already a hint for charge multiplication?
- High electric field reduces mobility of charge carriers
- Lorentz angle is also reduced
- Fraction of double hits is reduced
- Resolution slowly degrades up to the binary value (pitch/sqrt(12)
  - $\sim 30 \mu m$  with current pitch)



T. Rohe et al. Planar sensors for the upgrade of the CMS pixel detector, Pixel2020, Sep. 6-10, Grindelwald, CH

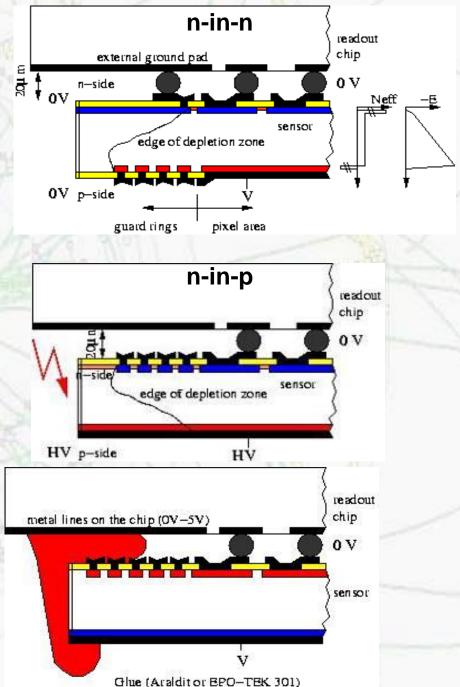
# **CMS Single-Sided (n-in-p) Sensors**

# Present CMS pixel detector uses n-in-n-sensors

- double sided processing (back side is structured)
- all sensor edges at ground
- most expensive part of the module (only bump-bonding is more expensive)

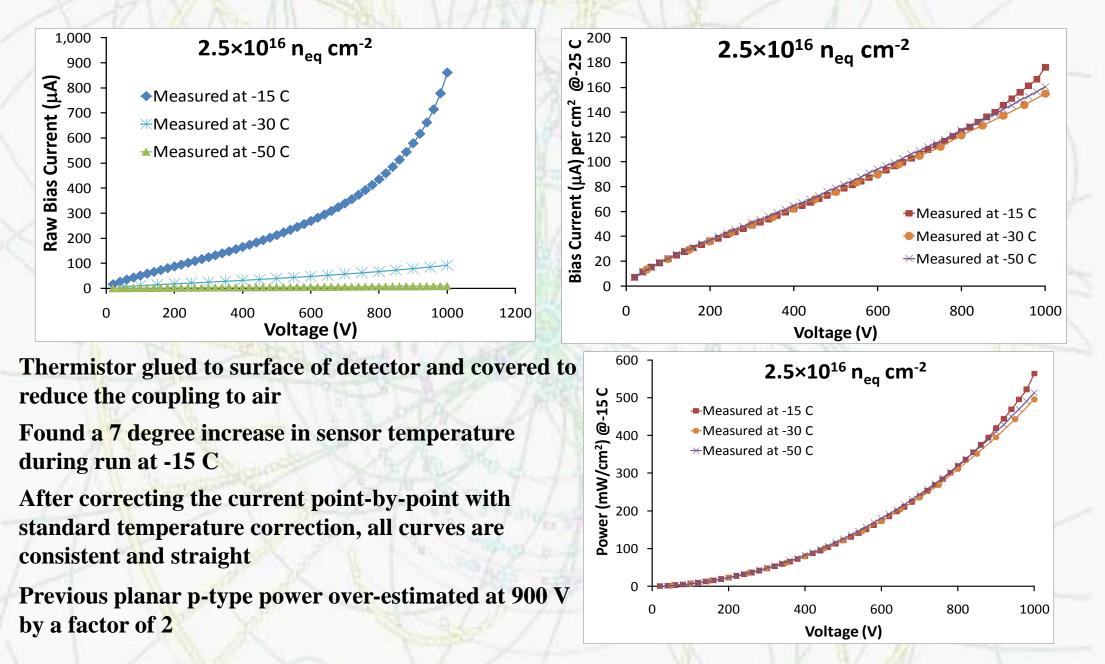
#### • Exploring n-in-p sensors as alternative

- recent studies show radiation hardness
- single sided process promise price benefit of factor 2-3
  - important as the pixel area will be doubled
- Absence of guard rings on back side lead to fear of (destructive) sparking to the ROC



T. Rohe et al. Planar sensors for the upgrade of the CMS pixel detector, Pixel2020, Sep. 6-10, Grindelwald, CH

## **Heavily Irradiated Micron n-in-p Pixel Sensor IV**



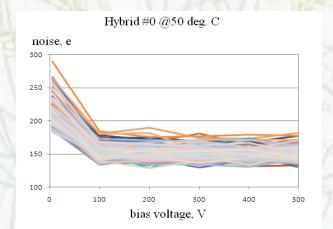
A. Affolder – ATLAS UK Planar Pixel Sensor R&D Meeting, 16 Sept 10 56

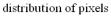
## Micron n-in-p Irradiated FE-I3 Pixel Package

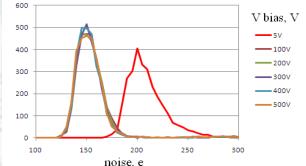


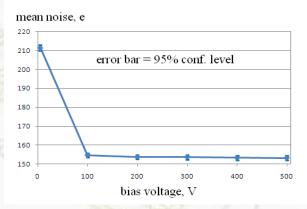
Measurements preirradiation and at doses of  $4 \times 10^{15}$  n<sub>eq</sub> cm<sup>-2</sup> and  $9 \times 10^{15}$  n<sub>eq</sub> cm<sup>-2</sup> all show no evidence of edge breakdown at 500V.

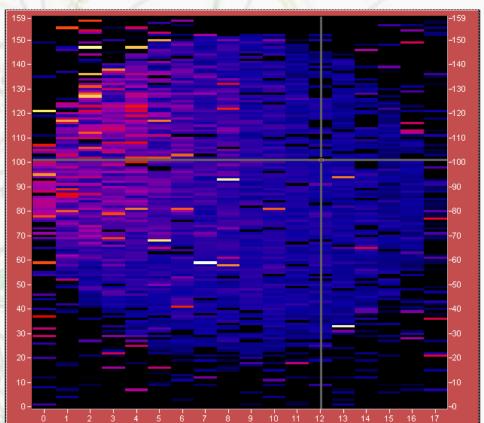
FE-I3 ASIC surprisingly robust but number of dead channels does increase at doses well above design target.



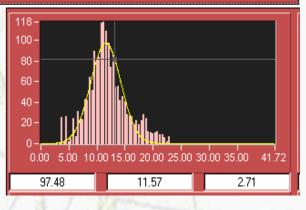








After irradiation to  $1.5 \times 10^{16}$  p/cm<sup>2</sup> At CERN PS (9×10<sup>15</sup> n<sub>eq</sub> cm<sup>-2</sup>) peak charge at 500V is ~4000e (Threshold 3500e -26 C, I<sub>b</sub> 44uA)



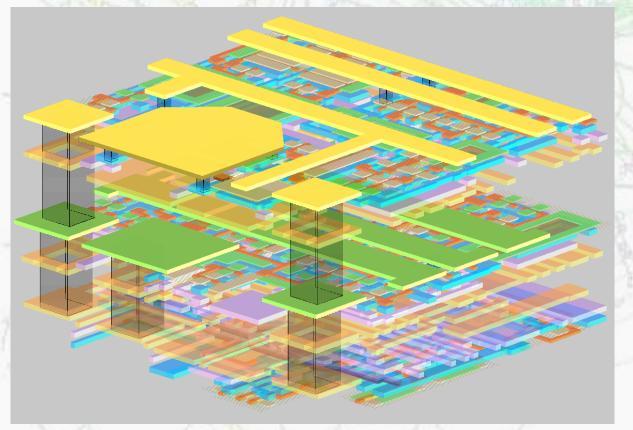
I. Tsurin – ATLAS UK Planar Pixel Sensor R&D Meeting, 16 Sept 10

## **Ultimate Interconnection: Vertical Integration**

Ideal solution for reducing material and easing assembly in detector system is to integrate electronics and sensors into a single item

#### ... if affordable

- This has been a "dream" for many years
- More complex detectors, low mass
- Liberate us from bump/wire bonding



Many different aspects of these new technologies such as SLID (solid liquid inter-diffusion), TSV (through silicon vias), ICV (inter-chip vias) as well as more highly integrated concepts.

Commercial technologies becoming available for custom design: IBM, NEC, Elpida, OKI, Tohoku, DALSA, Tezzaron, Ziptronix, Chartered, TSMC, RPI, IMEC.....

But are they all, or even, are any technologies radiation hard?

## Conclusions

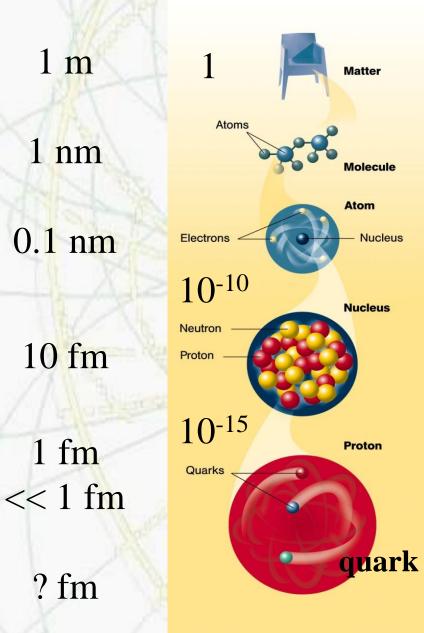
- The current LHC experiments required order-of-magnitude greater size, speed, granularity and radiation hardness than previous experiments.
- Nevertheless, all LHC experiments are performing exceptionally well.
- LHC performance is exceeding expectations and hopes are high for 2010/11.
- By the end of the decade there should be enough to revolutionise our understanding of physics at the TeV scale.
- However, the effective energy reach and ability to consolidate discoveries at the LHC are both enhanced significantly by a high luminosity upgrade.
- With 3000fb<sup>-1</sup>, the full potential of the LHC complex for energy frontier physics can be exploited.
- Such a super-LHC requires granularity and radiation hardness in the tracking detectors that are, again, a factor of 10 greater than before.
- A number of other future facilities are being actively planned, but some options will depend on the outcome of current experiments.
- Particle physics is poised on the brink of an era of unprecedented new discovery potential and technology development opportunities.

L-HENCISCON NO

# **Back-up Material**

## Introduction: What Everything is Made from

#### Distance

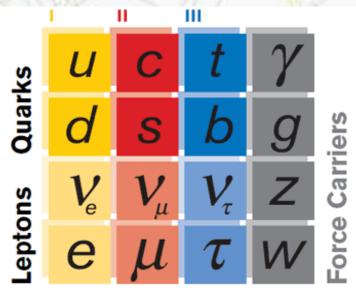


Forces	Energy
gravitation electro-	Radiation
	$\sim 0.01 \text{ eV}$ IR
magnetism	0.1 eV light
	>1  eV UV
	10 keV X-rays
strong	1 MeV αβγ
weak	0.1 GeV hadrons 1 GeV partons 100 GeV Z/W
	TeV ?

# **The Standard Model**

- Matter is made out of fermions:
  - 3 generations of quarks and leptons
- Forces are carried by Bosons:
  - Electroweak: γ,W,Z
  - Strong: gluons

		Measurement	Fit	0 <sup>m</sup> 0	eas_ 1	-O <sup>fit</sup>	∣/σ <sup>m</sup> 2	eas 3
-	$\Delta \alpha_{had}^{(5)}(m_Z)$	$0.02758 \pm 0.00035$	0.02767				T '	
		$91.1875 \pm 0.0021$	91.1875					
1	Г <sub>Z</sub> [GeV]	$2.4952 \pm 0.0023$	2.4958	-				6
¢	$\sigma_{had}^{0}$ [nb]	$41.540\pm0.037$	41.478					
		$20.767 \pm 0.025$	20.743					
	A <sup>0,I</sup>	$0.01714 \pm 0.00095$	0.01644					2
	Α <sub>I</sub> (Ρ <sub>τ</sub> )	$0.1465 \pm 0.0032$	0.1481	-				
	R <sub>b</sub>	$0.21629 \pm 0.00066$	0.21582		•			_
	R <sub>c</sub>	$0.1721 \pm 0.0030$	0.1722					
1	A <sup>0,b</sup>	$0.0992 \pm 0.0016$	0.1038					- 8
	A <sup>0,c</sup>	$0.0707 \pm 0.0035$	0.0742					
	A <sub>b</sub>	$0.923\pm0.020$	0.935					
1	A <sub>c</sub>	$0.670\pm0.027$	0.668					
1	A <sub>l</sub> (SLD)	$0.1513 \pm 0.0021$	0.1481					
	$\sin^2 \theta_{eff}^{lept}(Q_{fb})$	$0.2324 \pm 0.0012$	0.2314					
		$80.399 \pm 0.025$						1
1	Г <sub>w</sub> [GeV]	$2.098\pm0.048$	2.092					
1	m <sub>t</sub> [GeV]	$172.4\pm1.2$	172.5					
J	July 2008			0	1		2	3



**Three Generations of Matter** 

Remarkably successful description of known phenomena:
 predicted the existence of charm, bottom, top quarks, tau neutrino, W and Z bosons.
 Very good fit to the experimental data so far

but ...

# What We Don't Know: the Higgs

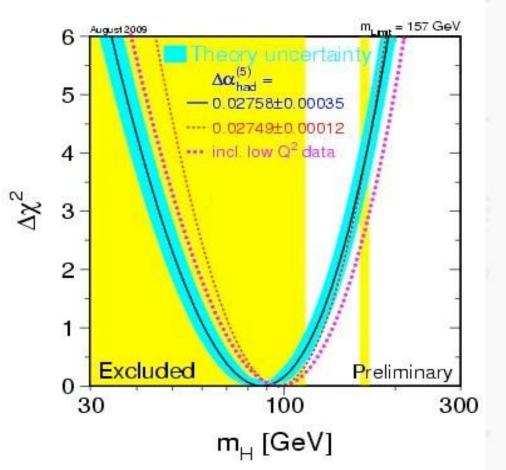
#### What is the origin of masses?

→ Within SM, **Higgs field** gives mass to Particles (E-W symmetry breaking)

 SM predicts existence of a new massive neutral particle

#### Not found yet!

- Theory does not predict its mass
- LEP limit: m<sub>H</sub>>114 GeV @ 95% CL
- Indirect limit from EW data:
  - Preferred value:  $m_H = 84^{+34}_{-26} \text{ GeV}$
  - m<sub>H</sub> < 154 GeV @ 95% CL

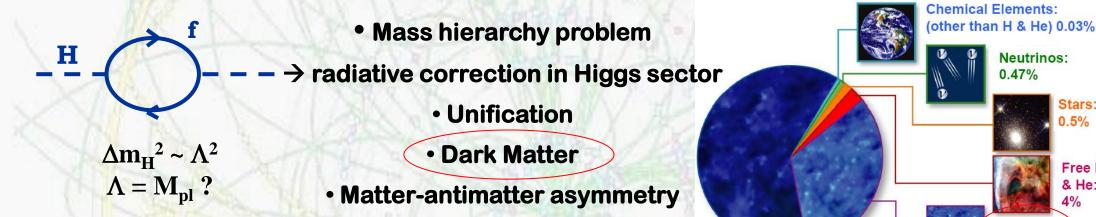


with  $\alpha_{\rm S}$  (M<sub>Z</sub>) = 0.1185 0.0026,  $\Delta \alpha_{\rm S}$ (5)<sub>had</sub>=0.02758 0.00035

## WOULD THE HIGGS DISCOVERY COMPLETE OUR UNDERSTANDING OF NATURE ?

# **Beyond SM:** the Unknown

### The Standard Model is theoretically incomplete



- Many possible new particles and theories
  - SuperSymmetry
  - Extra Dimension
  - New Gauge groups (Z', W')
  - New fermions (e<sup>\*</sup>, t', b' ...)

Can show up in direct searches or as subtle deviations in precision measurements

Stars:

Free H

& He:

Dark Matter

25%

**Dark Energy:** 

70%

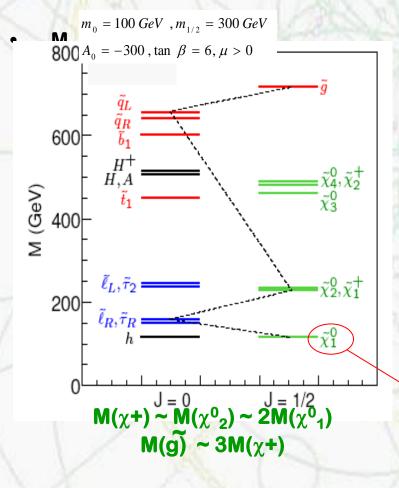
0.5%

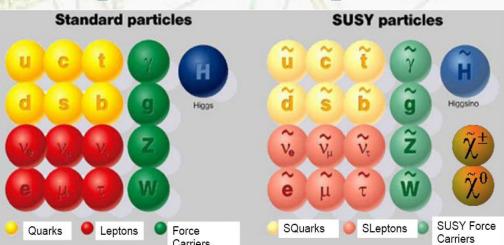
## **Search for SuperSymmetry**

 New spin-based symmetry relating fermions and bosons

#### Minimal SuperSymmetric SM(MSSM):

- Mirror spectrum of particles
- Enlarged Higgs sector: two doublets (5 physical states)





- Many searches but so far nothing seen and expected masses are above what could be probed at energies before the LHC
  - charginos/neutralinos > 165 GeV
  - squarks > 390 GeV (all gluino masses)
  - gluinos > 280 GeV (all squark masses)
  - Selptons > 100 GeV
  - stop > 200 GeV
  - sbottom > 240 GeV
  - limits on new higgs

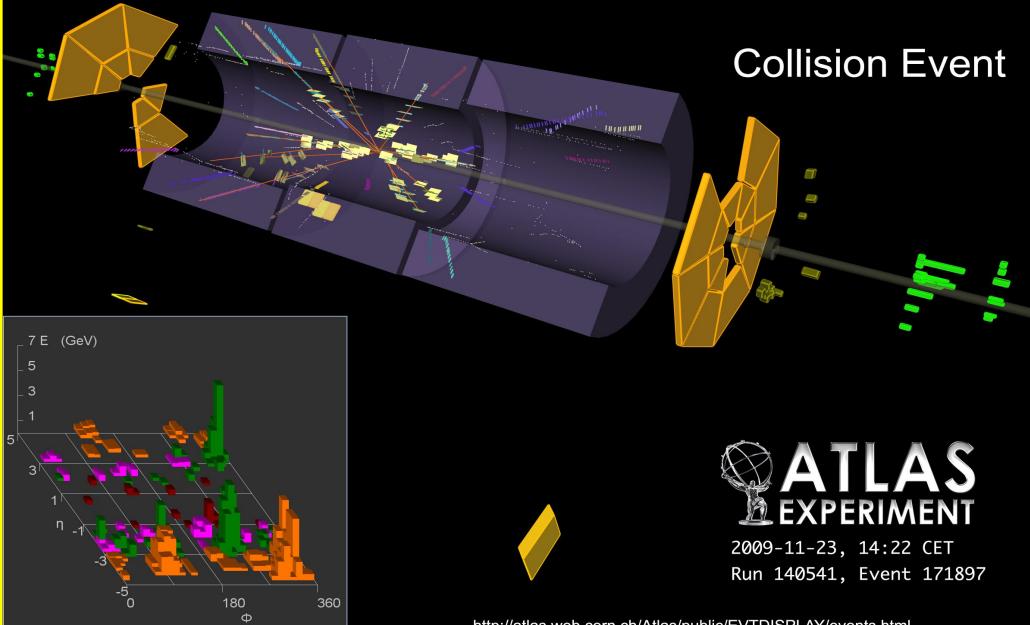
In this model, there is a spin-half partner to the photon that hardly interacts at all but is predicted to have the right range of masses and primordial densities to be the Dark Matter required by cosmologists.

#### **Real data starting at last ....**

## !!! BEAM AT ATLAS !!!! 20-11-09 20:47

66

#### Monday 23 November: first collisions at $\sqrt{s} = 900$ GeV ! $\rightarrow$ ATLAS records ~ 200 events (first one observed at 14:22)



http://atlas.web.cern.ch/Atlas/public/EVTDISPLAY/events.html

67

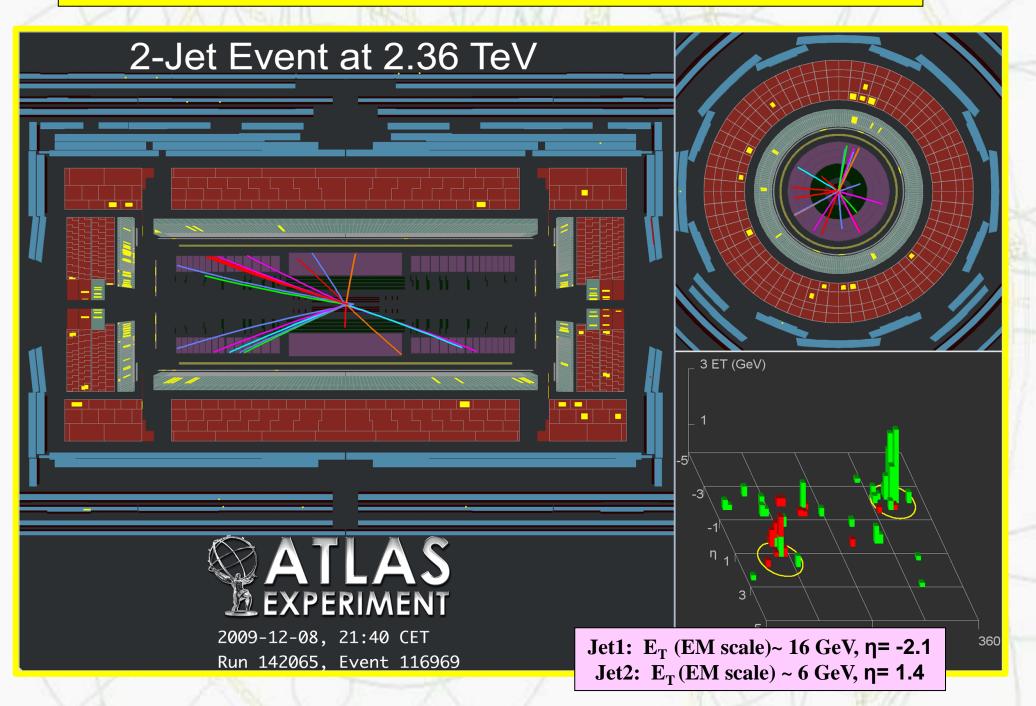


2009-12-06, 08:25 CET Run 141749, Event 133538

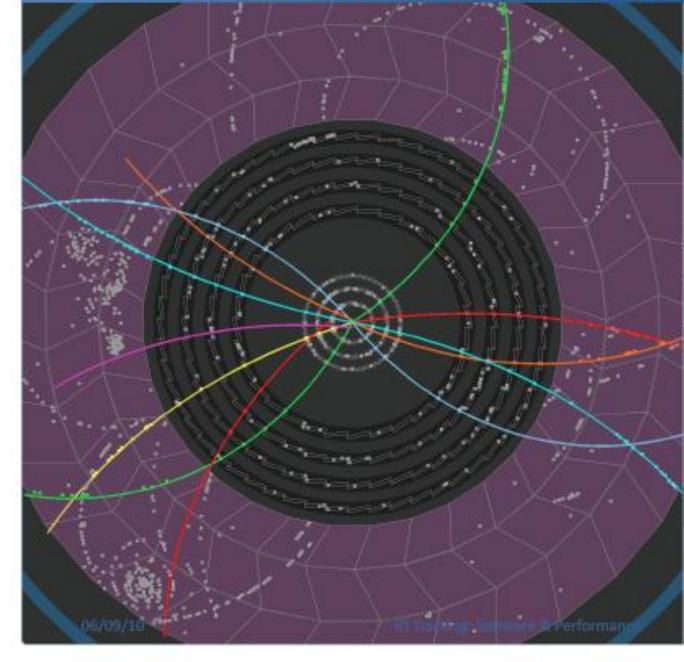
## Collision Event with 2 Muon Candidates

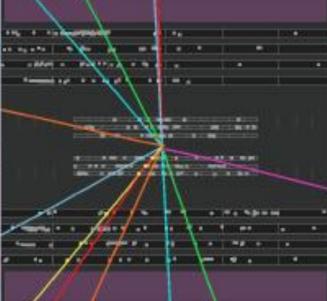
http://atlas.web.cern.ch/Atlas/public/EVTDISPLAY/events.html

#### 8, 14, 16 December: collisions at √s = 2.36 TeV (world record energy) →ATLAS records ~ 34000 proton-proton collision events



# Collisions with ID Fully Powered...







2009-12-06, 10:03 CET Run 141749, Event 405315

## **Collision Event**

## **Physics Reach at the LHC**

The challenge of the LHC is to cope with proton-proton collisions at GHz rates leading to up to 10<sup>16</sup> collision events per year, but where only a tiny fraction can be sensibly recorded

Most events do not correspond to the proton's constituents undergoing the head-on collisions that have the energies to make new particles

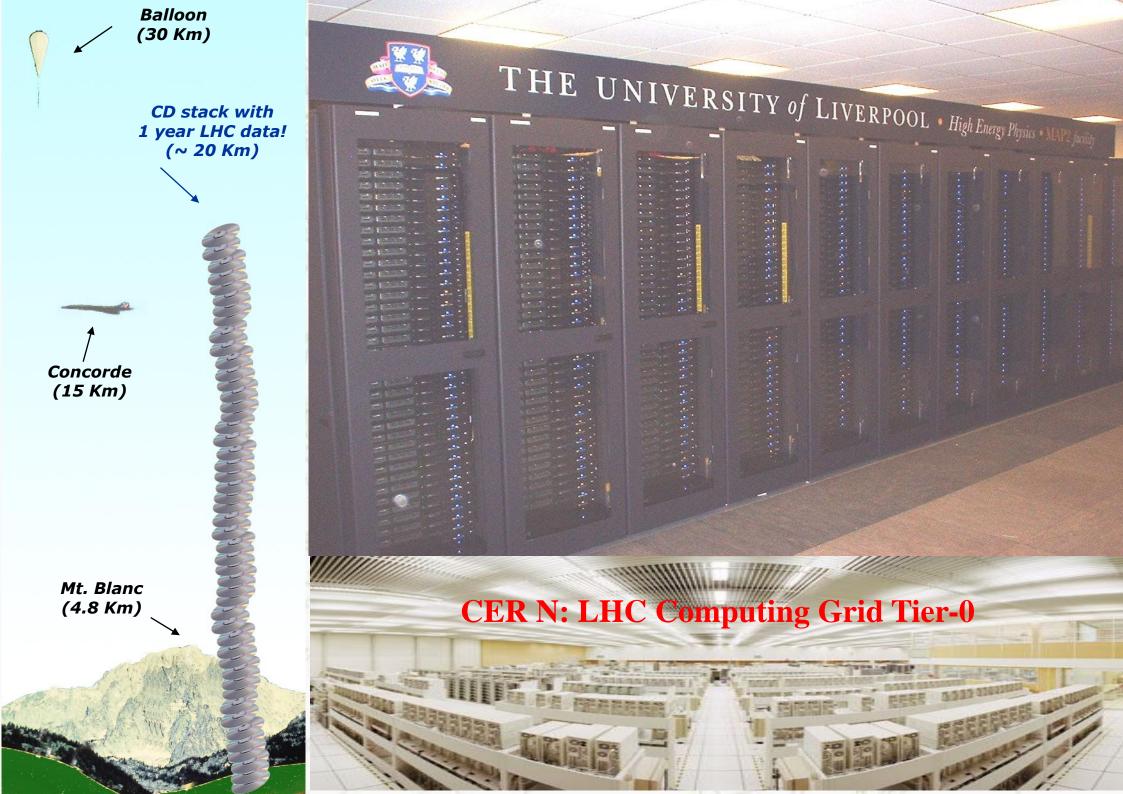
**Requires factors of several million fast, on-line, intelligent data filtering** 

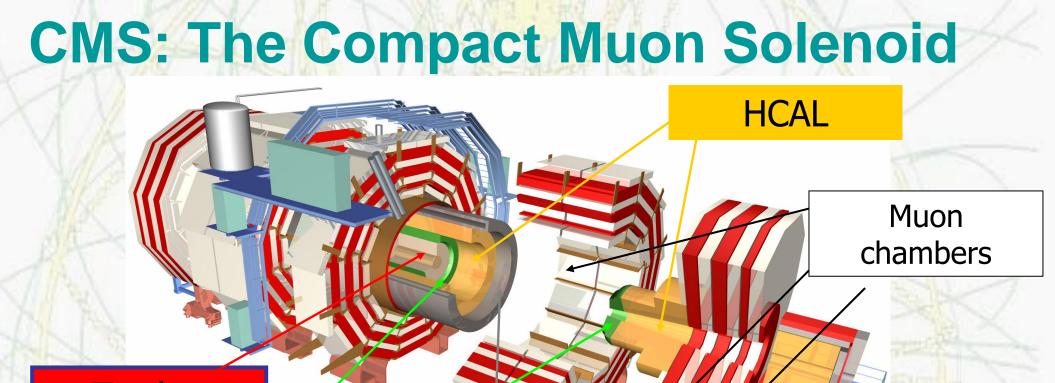
Even then, many tens of Petabytes per year need storing and processing

→ Worldwide LHC Computing Grid (WLCG of 100,000 processors at over 130 sites in 34 countries <u>http://lcg.web.cern.ch/LCG/public/</u>)



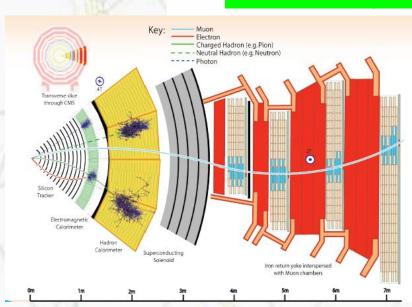
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Tracker

**ECAL** 



4T solenoid

Total weight: 12,500 t Overall diameter: 15 m Overall length 21.6 m Magnetic field 4 T

### **Examples of Expected Physics Gain**

(Physics case for **3000 fb<sup>-1</sup>** much better known after LHC first data analysed)

See Eur. Phys. J. C39(2005)293

• Precision Standard Model physics with up to 10 data (sensitive to new physics)

- Higgs couplings (eg  $\mu^+\mu^-$ ) and sensitivity to self-couplings
- Triple and quartic gauge couplings
- Strongly coupled vector-boson scattering (if there is no Higgs)
- Rare top decays through FCNC
- Extended mass reach for new particles (by additional ~0.5 to 1 TeV):
  - Heavy Higgs-bosons, extra gauge bosons, resonances in extra-dimension models, SuperSymmetry particles (if relatively heavy).

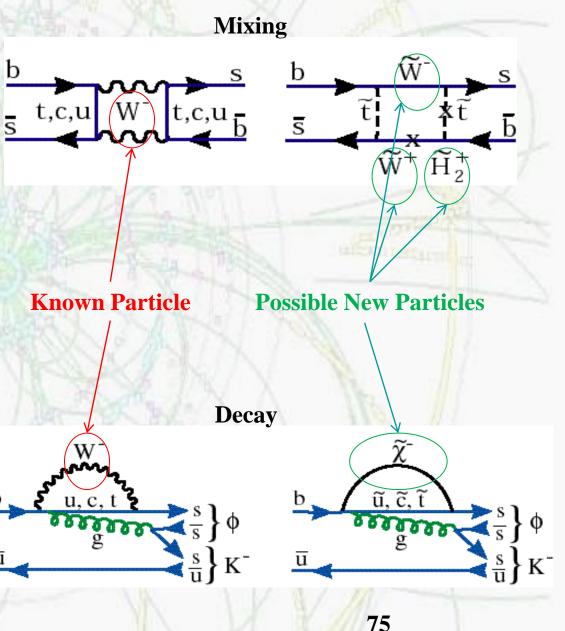
SuperSymmetry (if relatively light, already discovered at LHC)

- complete the particle spectrum
- access rare decay channels and measure branching ratios
- improve precision (e.g. to test against WMAP results)

• Because of statistics and mass reach, SLHC is to a large degree complementary to Linear Collider – LHC/SLHC can pair produce particles of ≥ TeV masses which couple predominantly through the strong interaction.

## Upgraded LHCb Reach

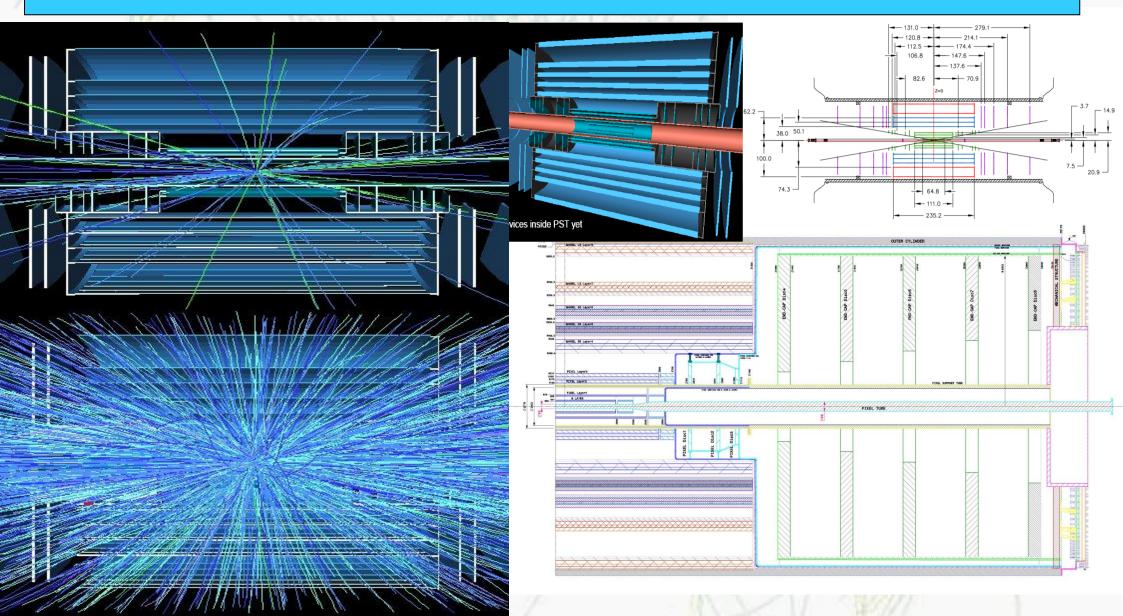
- To study even rarer processes need to upgrade the detector to b cope with multiple interactions per beam crossing (Go from short strips to 55µm×55µm pixels)
- Look for consequences for bdecays of new physics possibly found by ATLAS or CMS
- Upgrading will allow us to precisely measure these effects
- Complementary to studies possible using ATLAS and CMS and with other future proposed facilities eg "SuperB"

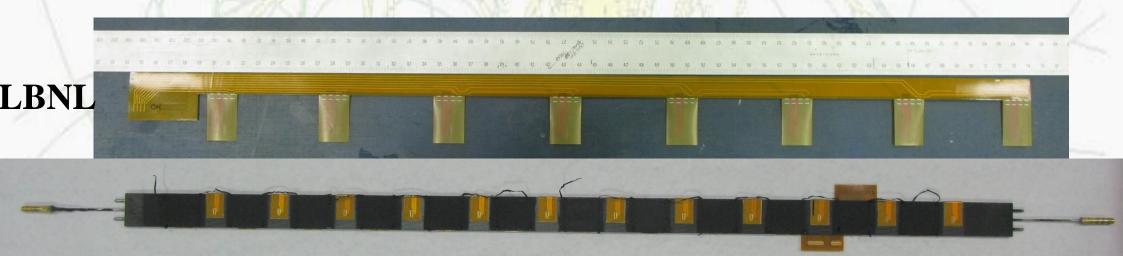


## **ATLAS Tracker Upgrade Layout**

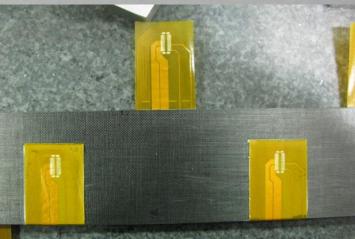
Barrel Pixel Tracker Layers: Short Strip (2.4 cm) μ-strips (stereo layers): Long Strip (9.6 cm) μ-strips (stereo layers): r = 3.7cm, 7.5cm, 15cm, 21cm r = 38cm, 50cm, 62cm

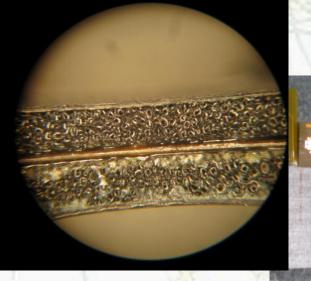
r = 74cm, 100cm





- Prototype cables made
- Embedded (glued) into 1m long stave
- Thermal, mechanical electrical testing just startin





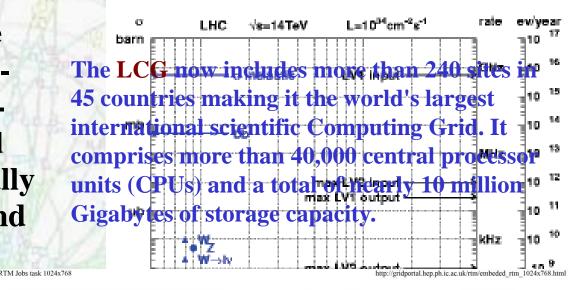


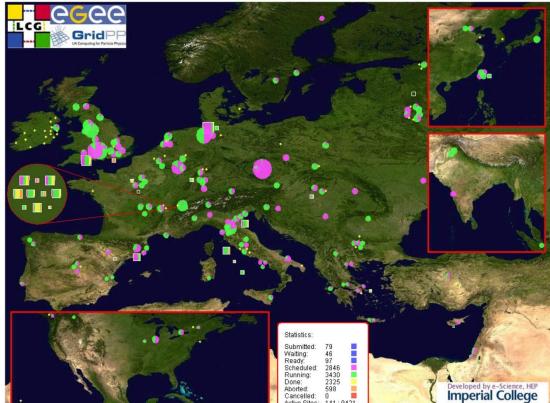
### **Data Processing Issues at the LHC**

The problem of the data deluge at the LHC both prompted sophisticated ondetector data reduction using a multitiered filtering "event triggering" and developments to harness internationally distributed large processing arrays and mass-storage, "Grid technologies".

'The Large Hadron Collider (LHC), currently being built at CERN near Geneva, is the largest scientific instrument on the planet. When it operates at full capacity, it will produce roughly 15 Petabytes (15 million Gigabytes) of data annually, which thousands of scientists around the world will access and analyse.

The mission of the LHC Computing Grid (LCG) Project is to build and maintain a data storage and analysis infrastructure for the entire high energy physics community that will use the LHC.'





### **CMS Planning for Upgrade Project**

- The SLHC planning assumptions keep changing in the light of experience with the machine and different ideas for achieving high luminosity running in a decade's time
- Developing and building a new tracker requires ~10 years
  - 5 years R&D
  - 2 years Qualification
  - 3 years Construction
  - 6 months Installation and Ready for Commissioning
- NB even this is aggressive
  - System design and attention to QA are important considerations from a very early stage
  - ff Hall Cost was a driver for LHC detectors from day one

## **CMS Tracker Services**

- Major constraint on upgraded system
  - Complex, congested routes
  - Heat load of cables must be removed
  - $P_{cable} = R_{cable} (P_{FE}/V_s)^2$
  - Cable voltage drops exceed read-out chip supply voltages
    - limited tolerance to voltage excursions

It will probably be impossible to replace cables and cooling for sLHC

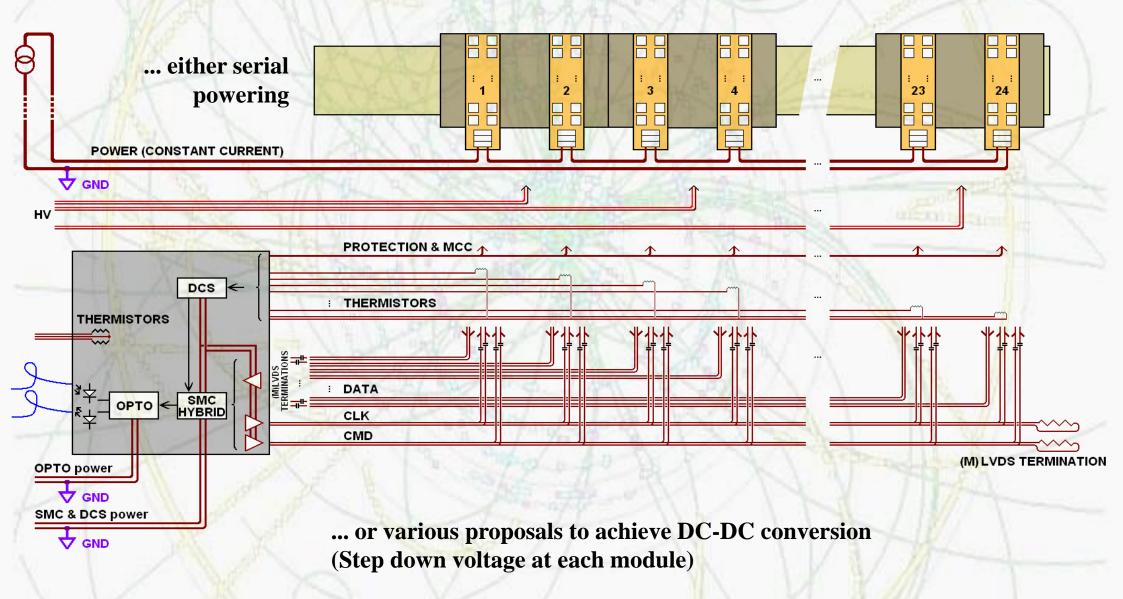
 $P_{FE} \approx 33 kW I = 15,500 A P_{S} = 300 kV A$ 

+X

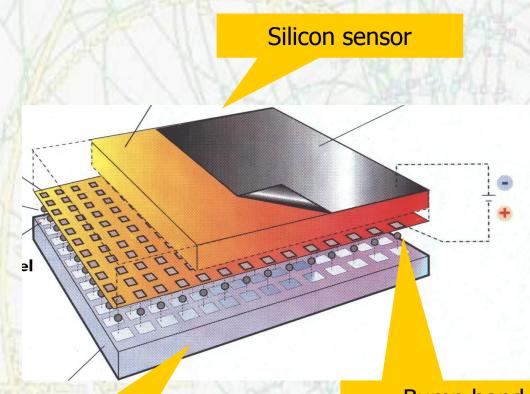
-Z

### **ATLAS Stave Electrical Concepts**

Need to bring in power at low current and high voltage but deep sub-micron ASICs operate at lower and lower voltages



### **Hybrid Pixel Detectors**



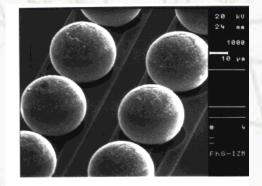
• Hybrid pixel detector:

- The sensor and the readout electronic are realized in different semiconductor substrates
- Size of the electronic readout pixels is equal to the size of the sensor pixels
- The connection between the electronic and the sensor is done via bump bond connections

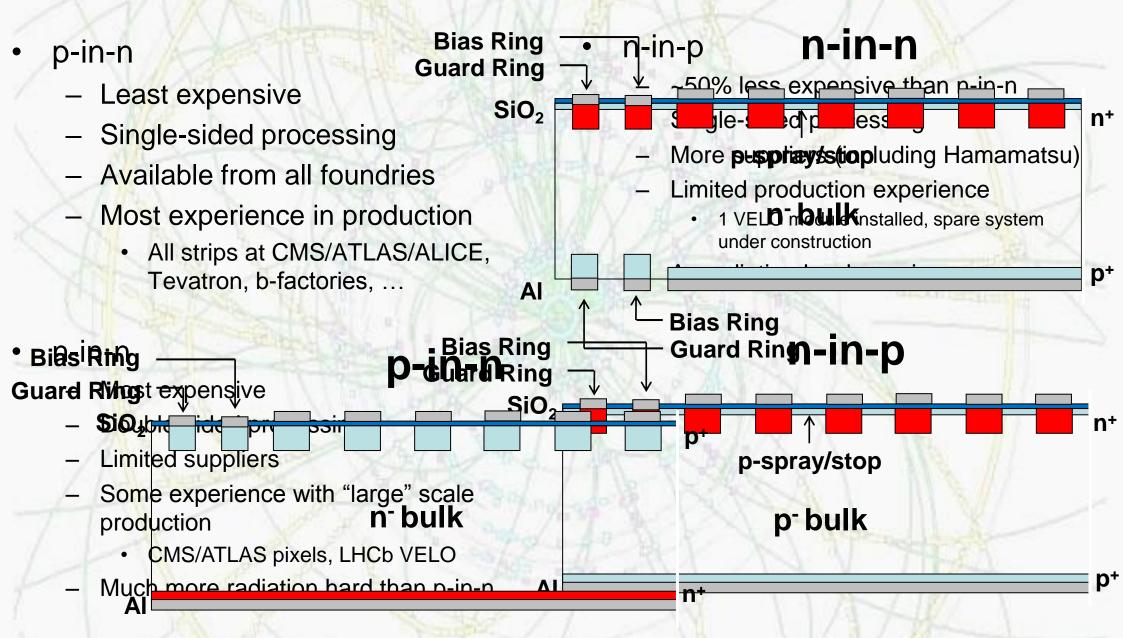
**Readout chip** 

**Bump bond** connection

- Bump bond technology: Size: 20 μm, pitch: 50 μm In (AMS) & PbSn (IZM) used for ATLAS pixel



## **Geometry Choices**

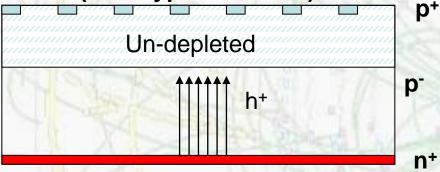


A. Affolder - PSD08, 1st-5th September 2008, Glasgow, Scotland

## **P-strip vs. N-strip Readout**

Effect of trapping on the Charge Collection Efficiency (CCE)

#### "Standard" p-in-n geometry (after type inversion)



### $Q_{tc} \cong Q_0 \exp(-t_c/\tau_{tr}), 1/\tau_{tr} = \beta \Phi.$

t<sub>c</sub> is collection "time", τ<sub>tr</sub> is effective trapping time **"New" n-in-p geometry "New" n-in-n geometry ( after type inversion)** n<sup>+</sup> p<sup>-</sup> Un-depleted p<sup>+</sup>

Type inversion turns lightly doped material to "p" type

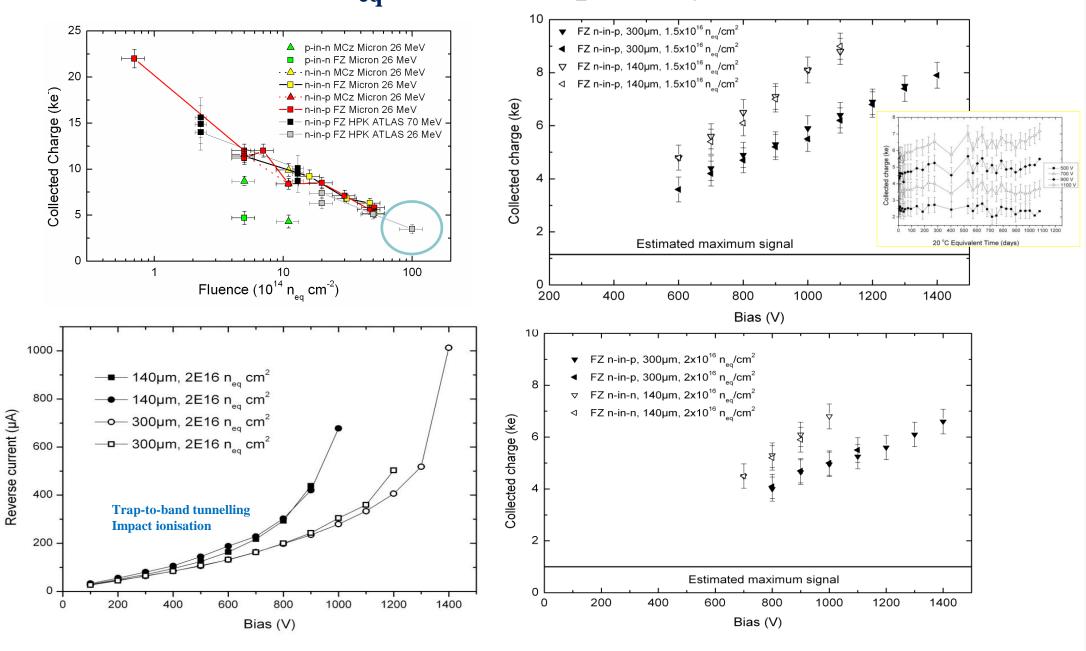
- Holes collected
- Deposited charge cannot reach electrode
  - Charge spread over many strips

- Electron collected
  - Higher mobility and ~33% smaller trapping constant
- Deposited charge can reach electrode

Lower signal

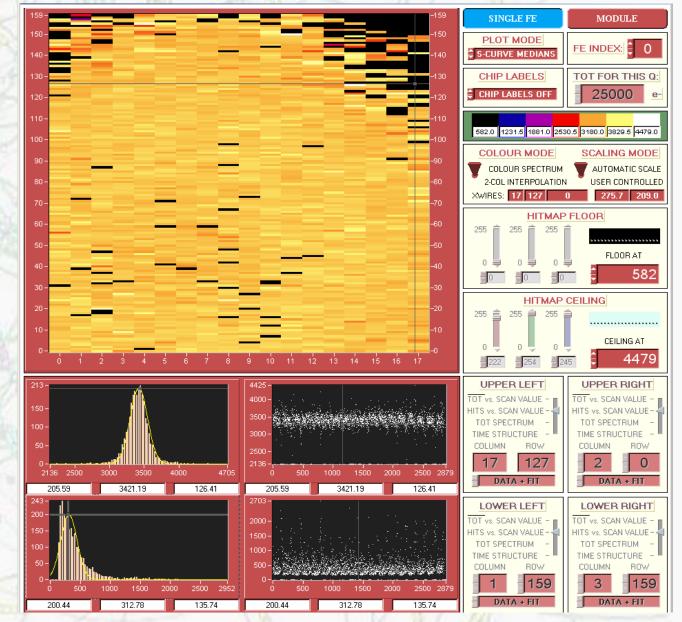
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### **n-in-p Planar Sensors at Extreme Doses** 1 and 2x10<sup>16</sup> n<sub>eq</sub> (innermost pixel layers at sLHC)



# FEI3 SCM 4×10<sup>15</sup> n<sub>eq</sub> cm<sup>-2</sup> Trimmed

- Measured at 500 V bias @-26 C
  - Most pixels trimmable
  - Noise and thresholds good
- Next step will be a source run. With an expected signal of ~5 ke<sup>-</sup> and <thr>=3500, we should see some of the landau at 500 V
- Once measured will increase bias voltage slowly and repeat

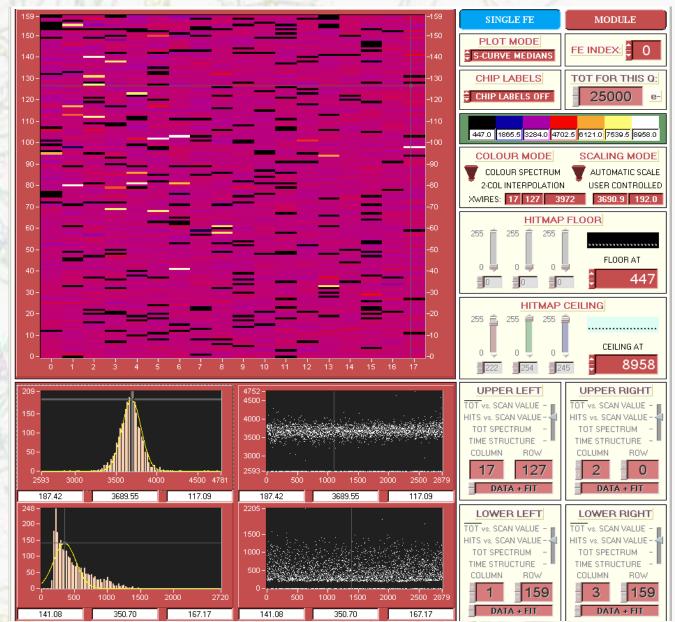


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# FEI3 SCM 9×10<sup>15</sup> n<sub>eq</sub> cm<sup>-2</sup> Trimmed

- Measured at 500 V bias @-26 C
  - Most pixels trimmable
  - Noise and thresholds good
- Next step will be a source run. Will need at least 800V to get to an expected signal of ~5 ke<sup>-</sup> and <thr>=3700, to some of the landau at 500 V
  - Once measured will increase bias voltage slowly and repeat

•

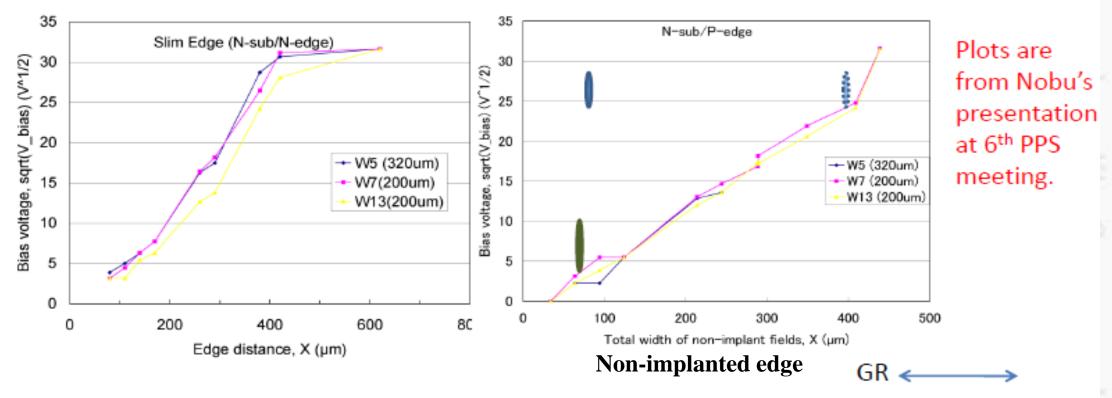


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### **Pre-irradiation**

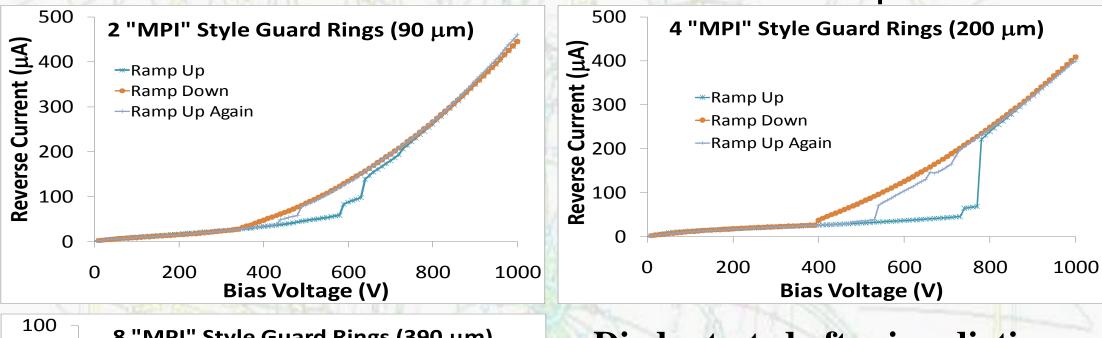
### Comparison with Nobu's presentation

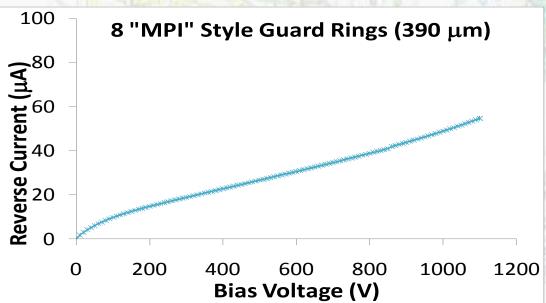
- Nobu showed a very interesting presentation during the last meeting.
- Observed the max bias voltage to depend only on (horizontal) unimplanted distance to the edge implant, not number of GRs.



- Best examples of p-type (green, 70 um) and n-type (blue, 78 um) extend above the very uniform dependence.
- Without edge implant, and with resistive edge, we have a different distance at play: depth matters (e.g. same point at the distance of 400 um detector thickness)! Activities at Santa Cruz, V. Fadeyev

# Slim Edges After 4×10<sup>15</sup> n<sub>eq</sub> cm<sup>-2</sup>





Diodes tested after irradiation •390 µm will hold 1100 V •Thinner structures show breakdown before 1000 V •It isn't clear if due to narrow edge •Or due to dicing cutting through outer guard ring due to miss alignment

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